



Products Catalog

Fixed Resistors

- General purpose chip resistors type
- High precision type
- Current sensing type
- Small & High power type
- Anti-Sulfurated type
- High temperature type
- Array type / Resistor network





Fixed Resistors (Surface Mount Resistors) INDEX

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*Not Recommended for New Design

Safety and Legal Matters to Be Observed

Product specifications and applications

- Please be advised that this product and product specifications are subject to change without notice for improvement purposes. Therefore, please request and confirm the latest delivery specifications that explain the specifications in detail before the final design, or purchase or use of the product, regardless of the application. In addition, do not use this product in any way that deviates from the contents of the company's delivery specifications.
- Unless otherwise specified in this catalog or the product specifications, this product is intended for use in general electronic equipment (AV products, home appliances, commercial equipment, office equipment, information and communication equipment, etc.).

When this product is used for the following special cases, the specification document suited to each application shall be signed/sealed (with Panasonic Industry and the user) in advance. These include applications requiring special quality and reliability, wherein their failures or malfunctions may directly threaten human life or cause harm to the human body (e.g.: space/aircraft equipment, transportation/traffic equipment, combustion equipment, medical equipment, disaster prevention/crime prevention equipment, safety equipment, etc.).

Safety design and product evaluation

- Please ensure safety through protection circuits, redundant circuits, etc., in the customer's system design so that a defect in our company's product will not endanger human life or cause other serious damage.
- This catalog shows the quality and performance of individual parts. The durability of parts varies depending on the usage environment and conditions. Therefore, please ensure to evaluate and confirm the state of each part after it has been mounted in your product in the actual operating environment before use. If you have any doubts about the safety of this product, then please notify us immediately, and be sure to conduct a technical review including the above protection circuits and redundant circuits at your company.

Laws / Regulations / Intellectual property

- The transportation of dangerous goods as designated by UN numbers, UN classifications, etc., does not apply to this product. In addition, when exporting products, product specifications, and technical information described in this catalog, please comply with the laws and regulations of the countries to which the products are exported, especially those concerning security export control.
- Each model of this product complies with the RoHS Directive (Restriction of the use of hazardous substances in electrical and electronic equipment) (2011/65/EU and (EU) 2015/863). The date of compliance with the RoHS Directive and REACH Regulation varies depending on the product model. Further, if you are using product models in stock and are not sure whether or not they comply with the RoHS Directive or REACH Regulation, please contact us by selecting "Sales Inquiry" from the inquiry form.
- During the manufacturing process of this product and any of its components and materials to be used, Panasonic Industry does not intentionally use ozone-depleting substances stipulated in the Montreal Protocol and specific bromine-based flame retardants such as PBBs (Poly-Brominated Biphenyls) / PBDEs (Poly-Brominated Diphenyl Ethers). In addition, the materials used in this product are all listed as existing chemical substances based on the Act on the Regulation of Manufacture and Evaluation of Chemical Substances.
- With regard to the disposal of this product, please confirm the disposal method in each country and region where it is incorporated into your company's product and used.
- The technical information contained in this catalog is intended to show only typical operation and application circuit examples of this product. This catalog does not guarantee that such information does not infringe upon the intellectual property rights of Panasonic Industry or any third party, nor imply that the license of such rights has been granted.
- Design, materials, or process related to technical owned by Panasonic Industry are subject to change without notice.

Panasonic Industry will assume no liability whatsoever if the use of our company's products deviates from the contents of this catalog or does not comply with the precautions. Please be advised of these restrictions.

Matters to Be Observed When Using This Product

(Fixed resistor)

Use environments and cleaning conditions

- This product (fixed resistor) is not designed for use in specific environments. Using the resistor in the following specific environments or service conditions may affect the performance/reliability of the resistor. Avoid using it in such specific environments. If you intend to use the resistor in such environments, checking the performance, reliability, etc., of the product sufficiently is your own responsibility.
 - (1) Used in liquid, such as water, oil, chemicals, and organic solvents.
 - (2) Used in a place exposed to direct sunlight, an outdoor place with no shielding, or a dusty place.
 - (3) Used in a place where the product is heavily exposed to sea breeze or a corrosive gas, such as Cl₂, H₂S, NH₃, SO₂, or NO_x.
 - (4) Used in an environment where static electricity and electromagnetic waves are strong.
 - (5) Located close to a heating component or a flammable material, such as a vinyl cable placed near the product.
 - (6) Sealed or coated with a resin.
 - (7) Solder flux of the resistor soldered with no-clean type solder, etc., is cleansed with a solvent, water, or a water-soluble cleaner, etc. (Water-soluble flux residues have a particularly large influence on a resistor.)
 - (8) Used in a place where dew concentrates on the product.
 - (9) Used in a contaminated state.

(Example: Touching the resistor mounted on a printed board leaving sebum on the resistor (improper handling))

- Sealing the resistor with a resin in a resin potting process, damp-proofing process, etc., applies excessive stress to the resistor, which may cause the internal electrodes a connection problem. In such cases, the proper operation of the resistor is not guaranteed. If you intend to use the resistor in such environments, checking the performance, reliability, etc., of the product sufficiently is your own responsibility.
- Do not leave the resistor immersed in a solvent for a long time. When using the resistor immersed in a solvent, confirm the operation of the product mounted on the board.
- When a cleaning solution or cleaning condition for cleaning the printed board or a drying condition for drying the printed board after soldering the resistor is improper, it may have a negative effect on the performance/reliability of the resistor. Confirming these conditions sufficiently is your own responsibility. Also examine the effects of soiled cleaning agent, cleaning residues, and post-cleaning contaminations, and control for these effects properly.

Response to anomalies and handling conditions

When the resistor is heating abnormally or emitting a smell, stop using the resistor immediately, for example, turn off the main power supply of the device.

Also, keep your face and hands away from the product as it may become hot and cause burns.

- The resistor is so thin that it may break easily when subjected to impact. Before putting the resistor in use, confirm that the resistor has not been broken by impact that applied thereto when mounted on the printed board. Applying impact to the resistor or pinching the resistor with a hard tool (pliers, tweezers, etc.) may chip the resistor or its protective film, which affects its performance. Be careful to avoid such cases.
- Do not reuse a resistor having been used on a printed board and removed therefrom. Do not touch the resistor with your bare hands.
- Be careful not to drop the resistor on the floor, etc. The resistor is likely to suffer mechanical or electrical damage when dropped on the floor. Avoid using said resistor.
- The resistor may have its resistance value changed due to electrostatic discharge (ESD). Take ESD prevention measures when handling the resistor. ESD prevention measures include an environment where static electricity is not likely to be generated (recommended RH: 40% to 60%), by wearing an earth band, conductive gloves, etc., grounding the device in which the resistor is incorporated, and placing a conductive mat, etc., on a work platform.
- It is guaranteed that a resistor not exposed to any stress will have its proper resistance value. Any stress or pressure applied to the resistor may cause its resistance value to change. Examine and evaluate the characteristics of the resistor sufficiently before using it.

Reliability and product life

A product conforming to "AEC-Q200" refers to a product having passed some or all of the evaluation test items defined in AEC-Q200. To know the detailed specifications of individual products or specific evaluation test scores, please contact us. We issue a delivery specification sheet for each product ordered. Please confirm with the sheet when you place an order with us.

Circuit design and circuit board design

- To prevent a case where a transient load (e.g., a pulse for a short period) too large for the product to handle is applied, make sure to evaluate and confirm the operation of the product incorporated in your product. Applying power or voltage (current) larger than the rated power or rated voltage (current) to the resistor may impair its performance and reliability. Make sure to use the resistor with power or voltage (current) equal to or lower than the rated power or rated voltage (current). The product warranty does not cover usage where an excessively large load, such as a pulse current, is applied to the product.
- The resistor may have a high temperature even when used with power equal to or lower than the rated power. Be careful in such cases. Another factor to be considered are effects on the board, peripheral components, etc., and the effects of peripheral components on the resistor. Make sure to confirm first that the temperature of the resistor incorporated in your product is equal to or lower than the specified temperature, and then use the resistor.
- When the resistors are connected in series or parallel, loads applied respectively to the resistors may not be equal to each other. Check whether the loads are equal in the actual circuit in which the resistors are incorporated.
- When a resistor is used in a high-frequency circuit, the resistor may fail to offer the required characteristics. Check whether the resistor offers the required characteristics in the actual circuit in which the resistors are incorporated.
- Be careful that unusual stress caused by an excessive bend of the printed board is not applied to the resistor. Design the circuit structure such that the resistor is not close to a perforated line for board splitting or on a line with sizable holes bored on the board.
- When a different component is mounted on the board where the resistor has been soldered, be careful that the board does not bend excessively. If necessary, provide the board with backup pins (support pins) to keep it straight.
- Avoid manual board splitting. Use a jig, etc., to break the board so that it does not bend excessively when split apart.

Mounting conditions

- When the product is used under mounting conditions departing from mounting conditions specified in our specification sheet, the product may be exposed to unexpected stress to fail. Be careful to avoid such a case. When mounting the resistor on a printed board, set the resistor's front and back surfaces in the direction indicated by the tape. Make sure to evaluate and confirm the operation of the resistor incorporated in your product and determine whether the resistor is usable as a component of the product.
- Set soldering conditions for the resistor within the recommended soldering conditions specified by our company. Any time, soldering condition departing from the specified soldering condition, such as a high peak temperature or a long heating may impair the performance/reliability of the resistor. Note that the specified soldering conditions indicate conditions under which degradation of the resistor characteristics does not occur but do not indicate conditions under which stable soldering can be performed. Check and set individual conditions under which stable soldering can be performed.
- Heat the resistor in advance so that a difference between the soldering temperature and the temperature of the resistor surface is reduced to 100 °C or lower. When dipping the soldered resistor in a solvent, etc., to cool the resistor rapidly, ensure that the temperature difference between the resistor and the solvent is 100 °C or lower during the dipping.
- When soldering the resistor using a soldering iron, apply hot air, etc., to the resistor to heat it sufficiently in advance and then solder the resistor without bringing the soldering iron tip into contact with the product. If the temperature of the soldering iron tip is high, finish the soldering work quickly (within 3 seconds when the temperature of the soldering iron tip is 350 °C or lower). In the case of a fixed resistor with low resistance, the resistor may fail to offer the exactly intended resistance value because of the variation in the solder volume, etc. Make sure to confirm the resistance value of the resistor in the actual circuit configuration.

- Soldering the resistor with too much solder or too little solder results in the poor reliability of the solder connection of the resistor. Use the proper volume of solder in the soldering process. Sufficiently check for the volume of solder used.
- Soldering with high bond strength or special property solder may affect the quality of the resistor. Do not use such solder.
- Use rosin-based solder flux. When using highly active solder flux made mainly of halogen (chlorine, bromine, etc.), flux residues may affect the performance and reliability of the resistor. Check the effects of flux residues before using the solder flux. Do not use highly acidic flux, water-soluble flux, or flux containing fluoride ions. When solder flux sticks to the resistor after the soldering process, the activation energy of the flux may corrode the resistor and cause it to fail. Prevent solder flux from sticking to the resistor.

Storage conditions

Keeping the product in the following environments or conditions may lead to degradation of its performance, solderability, etc. Do not keep the product in the following environments.

- (1) Stored in a place where the product is heavily exposed to sea breeze or a corrosive gas, such as Cl₂, H₂S, NH₃, SO₂, or NO_X.
- (2) Stored in a place where the product is exposed to direct sunlight.
- (3) Stored in a place where a temperature condition of 5 °C to 35 °C and a relative humidity condition of 45% to 85% cannot be maintained.
- (4) Kept in storage for more than one year from the delivery date (when the product is kept in conditions excluding any of the environments (1) to (3)).

Reference information

Guidelines

Before using the resistor, refer to the technical report issued by JEITA, EIAJ RCR-2121B "Safety Application Guide for Fixed Resistor for Use in Electronic Equipment" revised in February 2015.

Panasor

INDUSTRY

Thick Film Chip Resistors ERJ type ERJ XG, 1G, 2G, 3G, 6G series ERJ 8G, 14, 12, 12Z, 1T series

Features

- Small size and lightweight
- : Metal glaze thick film resistive element and three layers of electrodes High reliability
- Compatible with placement machines : Taping packaging available
- Suitable for both reflow and flow soldering
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJXG, ERJ1GN)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJ XGN, 1GN, 1GJ, 2GE, 3GE, 6GE, 8GE, 14, 12, 12Z, 1T series, ±5 %



* For the automotive application, please use ERJ1GJ as 0201 inch size from the new design.

Not recommended for new design





(Oct. 2021) Products marked as "NRFND" are not recommended for new design Target products : ERJ8G, 14, 12, 12Z, 1T series Please refer to the recommended alternatives with "Design Support Tool"

Thick Film Chip Resistors

Ratings

[For Resistor]

Part No. (inch size)	Rated power ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resis ran (ເ	tance ge 2)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJXG (01005)	0.031	15	30	±5	1 to 1 M	(E24)	R<10Ω : −100 to +600 10Ω to 100Ω : ±300 100Ω≤R : ±200		-
ERJ1GN (0201)	0.05	25	50	±5	1 to 10 M	(E24)		-55 to +125	
ERJ1GJ (0201)	0.05	25	50	±5	1 to 10 M	(E24)	R<10 Ω : –100 to +600		Grade 1
ERJ2G (0402)	0.1	50	100	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω : ±200		
ERJ3G (0603)	0.1	75	150	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" :="" td="" to="" –400=""><td>-55 to +155</td><td>Grade 0</td></r>	-55 to +155	Grade 0
ERJ6G (0805)	0.125	150	200	±5	1 to 10 M	(E24)			
ERJ8G (1206)	0.25	200	400	±5	1 to 10 M	(E24)			
RFND ERJ14 (1210)	0.5	200	400	±5	1 to 10 M	(E24)	R<10 Ω : -100 to +600		
REND ERJ12 (1812)	0.75	200	500	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω : ±200	-55 to +155	Grade 0
ERJ12Z (2010)	0.75	200	500	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
ERJ1T (2512)	1	200	500	±5	1 to 1 M	(E24)			

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

	Part No.	Resistance(Ω)	Rated current(A)	Maximum overload current (A) ^{*1}
	ERJXG		0.5	1
	ERJ1G		0.5	I
	ERJ2G	50 m Ω or less	1	2
	ERJ3G		I	2
	ERJ6G		2	4
NR	ND ERJ8G			
NR	₪ ERJ14			
NRF	ERJ12	50 m Ω or less	2	4
NR	ERJ12Z			
NRF	ERJ1T			

[For Jumper]

N

* 1 :Overload test current

Construction



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.



above 70 ℃, power rating shall be derated in accordance with the figure below.

Power derating curve



Thick Film Chip Resistors

Dimensions (not to scale)



						Unit . Initi				
Part No			Dimensions							
Fait NO.	L	W	а	b	Т	(g/1000 pcs)				
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04				
ERJ1G	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15				
ERJ2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8				
ERJ3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2				
ERJ6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4				
NRFND ERJ8G	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10				
NRFND ERJ14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16				
NREND ERJ12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27				
NREND ERJ12Z	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27				
NREND ERJ1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45				

NRFND Not recommended for new design

Performance

Toot itom	Performance re	equirements ⊿R	Test conditions
rest ttem	Resistor type	Jumper type	rest conditions
Resistance	Within specified tolerance	50 m Ω or less	20 °C
T. C. R.	Within specified T. C. R.	50 m Ω or less	+25℃ / +155℃ (ERJXG,1G : +25℃ / +125℃)
Overload	+2 %	50 mO or less	Rated voltage× 2.5, 5 s
	12 /0	30 1122 01 1033	Jumper type : Max. overload current, 5 s
Resistance to soldering heat	±1 %	50 m Ω or less	270 ℃, 10 s
Rapid change of	+1 %	50 mO or less	–55 ℃ (30 min.) / +155 ℃ (ERJXG,1G : +125 ℃)
temperature	11 /0	50 1122 01 1635	(30 min.), 100 cycles
High temperature exposure	±1 %	50 m Ω or less	+155℃ (ERJXG,1G : +125℃), 1000 h
Damp heat, Steady state	±1 %	50 m Ω or less	60 ℃, 90 % to 95 %RH, 1000 h
			60 ℃, 90 % to 95 %RH,
Load life in humidity	±3 %	50 m Ω or less	Rated voltage (Jumper type :Rated current),
			1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70°C	+3 %	50 mO or less	70 $^{\circ}$ C, Rated voltage (Jumper type : Rated current),
Endurance at 70 C	±3 % 50 mΩ or less		1.5 h ON / 0.5 h OFF cycle, 1000 h

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Panasonic

INDUSTRY

Precision Thick Film Chip Resistors

ERJ type

- ERJ XG, 1G series
- ERJ 1R, 2R, 3R, 6R series
- ERJ 3E, 6E, 8E, 14, 12, 1T series





(Oct. 2021) Products marked as "NRFND" are not recommended for new design. Target products : ERJ8E, 14, 12, 1Tseries Please refer to the recommended alternatives with "Design Support Tool" -

Features

- Small size and lightweight
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Compatible with placement machines : Taping packaging available
- Suitable for both reflow and flow soldering
- Low resistance tolerance : ERJXG, 1G, 2R, 3E, 6E, 8E, 14, 12, 1T series : ±1 % ERJ1R, 2R, 3R, 6R series : ±0.5 %
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJ1R, ERJXG, ERJ1GN)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.





The first three digits are significant figures of resistance and the last one denotes number of zeros following. Example : $1002 \rightarrow 10 \text{ K}\Omega$

Precision Thick Film Chip Resistors

Aplanation											
		Note	: Please che	eck the '	'Ratings" fo	the presence/abse	ence of part	number	s for c	ombinations of the s	ymbols b
ERJ XGN.	1GN	J. 1G	J. 2RC. 2	2RK.	3EK. 6E	N 8EN. 14N	l. 12N. 1	12S. 1	ΤN	series : ±1 %	
,		.,	-,,_	,	,	,,	-,,				
1 2	3	3	4 5	5	6	7 8	9	10	11	12	
= р			8	-	N	E 1	0	Δ	2	V	
-	·	•	0	-			U	U	2	V	
		Г		1							
roduct code	S	Size, Pow	er rating	Resis	tance toleranc	e Resista	nce value			Packaging methods	
Thick film	Code	inch	Power rating	Code	Tolerance				Code	Packaging	Part No.
nip resistors	XGN	01005	0.031 W	F	±1 %	The first three dig	jits are signifio	cant	Y	Pressed carrier taping	
	1GN	0201	0.05 W			figures of resistar	nce and the la	st	'	W8P2, 20,000 pcs	FRJXGN
	1GJ	0201	0.05 W			following.			U	Embossed carrier taping	Litertoit
	2RC	0402	0.1 W			Decimal point is e	expressed by	"R".	-	W4P1, 40,000 pcs	
	2RK	0402	0.1 W			Example : 1002 -	→ 10 kΩ		С	Pressed carrier taping	ERJ1GN
	3EK	0603	0.1 W						-	2 mm pitch, 15,000 pcs	ERJ1GJ
	6EN	0805	0.125 W						х	Punched carrier taping	ERJ2RC
NRFND	8EN	1206	0.25 W							2 mm pitch, 10,000 pcs	ERJ2RK
NRFND	14N	1210	0.5 W							Dunched continuing	ERJ3EK
NRFND	12N	1812	0.75 W						V	4 mm pitch, 5,000 pcs	ERJ6EN
NRFND	12S	2010	0.75 W							NRFND	ERJ8EN
NRFND	1TN	2512	1 W					NRFND	U	Embossed carrier taping 4 mm pitch, 5,000 pcs	ERJ14N ERJ12N ERJ12S
* For the	automo	tive appli	cation, please ι	ise ERJ1	GJ as 0201 i	nch size from the new	design.		0	Embossed carrier taping 4 mm pitch, 4,000 pcs	ERJ1TN

NRFND Not recommended for new design

Ratings

<+0.5 %>

1010 /	-								
Part No. (inch size)	Rated power ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resist ran (Ω	ance ge !)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJ1RH (0201)	0.05	15	30	±0.5	1 k to 1 M	(E24,E96)	±50	-55 to +125	-
ERJ2RH (0402)	0.063	50	100	±0.5	100 to 100 k	(E24,E96)	±50		
ERJ2RK (0402)	0.063	50	100	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100		
ERJ3RB (0603)	0.1	75	150	±0.5	100 to 100 k	(E24,E96)	±50	EE to 1 1EE	Crada 0
ERJ3RE (0603)	0.1	75	150	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 10 + 155	Grade 0
ERJ6RB (0805)	0.1	150	200	±0.5	100 to 100 k	(E24,E96)	±50		
ERJ6RE (0805)	0.1	150	200	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100		

*1 : Use it on the condition that the case temperature is below the upper category temperature.

*2 : Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or limiting element voltage listed above, whichever less.

*3 : Overload test voltage (OTV) shall be determined from OTV = specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change managements and set of the set of t

Precision Thick Film Chip Resistors

Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resis rai (!	stance nge Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJXGN (01005)	0.031	15	30	±1	10 to 1 M ^{*4}	(E24,E96)	$R < 100 \ \Omega : \pm 300$ $100 \ \Omega \le R : \pm 200$		
ERJ1GN (0201)	0.05	25	50	±1	10 to 1 M ^{*4}	(E24,E96)	+200	-55 to +125	-
ERJ1GJ (0201)	0.05	25	50	±1	10 to 1 M ^{*4}	(E24,E96)	1200		Grade 1
ERJ2RC (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600		
ERJ2RK (0402)	0.1	50	100	±1	10 to 1 M	(E24,E96)		55 to + 155	Grade 0
ERJ3EK (0603)	0.1	75	150	±1	10 to 1 M	(E24,E96)	±100	-55 10 + 155	Glade U
ERJ6EN (0805)	0.125	150	200	±1	10 to 2.2 M	(E24,E96)			
ERJ8EN (1206)	0.25	200	400	±1	10 to 2.2 M	(E24,E96)			
ERJ14N (1210)	0.5	200	400	±1	10 to 1 M	(E24,E96)			
ERJ12N (1812)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ12S (2010)	0.75	200	500	±1	10 to 1 M	(E24,E96)			
ERJ1TN (2512)	1	200	500	±1	10 to 1 M	(E24,E96)			

*1 : Use it on the condition that the case temperature is below the upper category temperature.

*2 : Rated continuous working voltage (RCWV) shall be determined from RCWV= √Power rating × Resistance value, or limiting element voltage listed above, whichever less.

*3 : Overload test voltage (OTV) shall be determined from OTV = specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

*4 : Please contact us when you need a type with a resistance of less than 10 Ω .

Power derating curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



NRFND

Construction



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change management response to contact us immediately. Should a safety concern arise regarding this product, please be sure to contact us immediately. 10

Not recommended for new design

Precision Thick Film Chip Resistors

Dimensions (not to scale)



Dort No.			Dimensions (mm)			Mass (Weight)	
Part No.	L	W	а	b	Т	(g/1000 pcs)	
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04	
ERJ1G	0.60+0.03	0.30+0.03	0 10+0 05	0 15+0 05	0.23+0.03	0.15	
ERJ1R	0.00±0.05	0.30±0.03	0.1010.05	0.1510.05	0.2510.05	0.15	
ERJ2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8	
ERJ3R	1 60+0 15	0.80+0.15/-0.05	0 30+0 20	0 30+0 15	0.45+0.10	2	
ERJ3E	1.00±0.13 0.00+0.13/-0.03		0.0010.20	0.0010.20 0.0010.10 0.40.			
ERJ6R	2 00+0 20	1 25+0 10	0.40+0.20	0 40+0 20	0.60+0.10	1	
ERJ6E	2.00±0.20	1.2510.10	0.4010.20	0.4010.20	0.0010.10	-	
NREND ERJ8EN	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10	
NREND ERJ14N	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16	
NRFND ERJ12N	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27	
NREND ERJ12S	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27	
NREND ERJ1TN	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45	

NRFND Not recommended for new design

Performance

• ERJ 1R, 2R, 3R, 6R series : ±0.5 % (D)

Test item	Performance	Test conditions	
i est tterit	requirements ⊿R		
Resistance	Within specified	20 °C	
Resistance	tolerance	20 C	
тср	Within specified	±25 °C / ±125 °C	
1. C. K.	T. C. R.	+25 C7 +125 C	
Overload	±2 %	Rated voltage × 2.5, 5 s	
Resistance to soldering heat	±1 %	270 ℃, 10 s	
Rapid change of temperature	+1 %	–55 ℃ (30 min.) / +155 ℃ (ERJ1R : +125 ℃)(30 min.),	
Rapid change of temperature	1 /0	100 cycles	
High temperature exposure	±1 %	+155 ℃ (ERJ1R : +125 ℃), 1000 h	
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h	
Lood life in humidity	±2 %	60 ℃, 90 % to 95 %RH, Rated voltage,	
Load me in numulty	ERJ1R : ±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h	
Endurance at 70 ℃	±2 %	70 °C, Rated voltage, 1.5 h ON / 0.5 h OFF cvcle, 1000 h	
	ERJ1R : ±3 %		

• ERJ XGN, 1GN, 1GJ, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN series : ±1 % (F)

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃ (ERJXG,ERJ1G : +25℃ / +125 ℃)
Overload	±2 %	Rated voltage × 2.5, 5 s
Resistance to soldering heat	±1 %	270 °C, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.)/+155 ℃ (ERJXG,ERJ1G : +125 ℃)(30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃ (ERJXG,ERJ1G : +125 ℃), 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±2 %	60 ℃, 90 % to 95 %RH, Rated voltage,
	ERJXG,1G : ±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±2 % ERJXG,1G : ±3 %	70 °C, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Should a safety concern arise regarding this product, please be sure to contact us immediately.

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INDUSTRY

Thin Film Chip Resistors, **High Voltage Type**



ERA P type

ERA 8P series

Features

- High voltage
- High reliability
- High accuracy
- High performance
- Anti-ESD
- (AEC-Q200-002 HBM Guarantee at 4 kV) : Original structure for sulfurated performance
- Anti-sulfurated Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

: Original structure for high ESD performance

: Stable at high temperature and humidity

: Low current noise, excellent linearity

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

: Achieves high limiting element voltage with original design concept (500V @ $1M\Omega$)

(85 \degree 85 %RH rated load, Category temperature range : -55 \degree to +155 \degree)

: Low resistance tolerance and temperature coefficient of resistance



Rating	Ratings									
Part No. (inch size)	Power rating at 85 ℃ ^{*1} (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage (V)	Part No. (detail)	Resistance tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Resistanc (Ω	e range ^{*3} 2)	Category temperature range (°C)	AEC-Q200 Grade
ERA8P	0.25	500	1000	ERA8PEB	+0.1	±25	160 k to 1 M	(E24 E96)	55 to +155	Grade 0
(1206)	0.25	500	1000	ERA8PPB	10.1	±15	TOOKIOTIVI	(L24, L30)	-33 10 1 133	Orace 0

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated continuous working voltage (RCWV) shall be determined from RCWV= (Power Rating × Resistance Values), or limiting element voltage listed above, whichever less.

*3: E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.

Power derating curve

For resistors operated in ambient temperatures above 85°C, power rating shall be derated in accordance with the figure on the right.



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use Design and specifications are each subject to orange matched to contact us immediately. Should a safety concern arise regarding this product, please be sure to contact us immediately. 12

Thin Film Chip Resistors, High Voltage Type



Dimensions (not to scale)



						Unit : mm			
Part No.	Dimensions								
	L	W	а	b	Т	(g/1000 pcs)			
ERA8P	3.20±0.20	1.60±0.10	0.50±0.20	0.50±0.20	0.55±0.10	10			

Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±0.1 %	Specified magnification (2.5) × RCWV or Maximum overload voltage, whichever less, 5 s
Resistance to soldering heat	±0.1 %	270 ℃, 10 s
Rapid change of temperature	±0.1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 1000 cycles
High temperature exposure	±0.1 %	+155 ℃, 1000 h
Damp heat, Steady state	±0.1 %	85 °C, 85 %RH, 1000 h
Load life in humidity	±0.1 %	85 ℃, 85 %RH, 10 % of Rated power ^{*1} , 1.5 h ON / 0.5 h OFF cycle , 1000 h
Endurance at 85℃	±0.1 %	85 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Electro static discharge (HBM)	±0.1 %	AEC-Q200-002 [:] 150 pF, 2000 Ω, positive 5 times, negative 5 times
		ERA8P : 4.0 kV (Class 3)

*1: Applied Voltage is " $\sqrt{0.1 \times \text{Power Rating} \times \text{Resistance Values}}$ ".

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to charge without notice, the subject to charge without notice, the subject to charge without notice to contact us immediately. Should a safety concern arise regarding this product, please be sure to contact us immediately. 13

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INDUSTRY

Thin Film Chip Resistors, **High Stability and Reliability Type ERA V type**

(High resistance value ERA K type)

ERA 2V, 3V, 6V, 8V series (ERA 3K, 6K, 8K series)

Features

- : To realize higher power rating, Limiting element voltage, and maximum High Power overload voltage than current products : Stable at high temperature and humidity High reliability (85 °C 85 %RH rated load, Category temperature range : -55 °C to +155 °C) High accuracy : Low resistance tolerance and temperature coefficient of resistance High performance : Low current noise, excellent linearity Anti-ESD : Original structure for high ESD performance (AEC-Q200-002 HBM Class 1c and above) Anti-sulfurated : Original structure for sulfurated performance
- : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C Reference standard
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions. please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Thin Film Chip Resistors, High Stability and Reliability Type

Rating	S																			
Part No. (inch size)	Power rating at 85 ℃ ^{*1} (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Part No. (detail)	Resistance tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Resistand (S	ce range ^{*4} Ω)	Category temperature range (℃)	AEC-Q200 Grade										
				ERA2VEB	±0.1	±25	47 to 100 k ^{*5}	(E24, E96)												
ERA2V	0.1	75	150	ERA2VPB	±0.1	±15														
(0402)	0.1	15	150	ERA2VRB	±0.1	+10	1 k to 47 k *5	(E24, E96)												
				ERA2VRW	±0.05	10														
				ERA3VEB	±0.1	±25	47 to 100 k	(E24, E96)												
ERA3V	ERA3V (0603) 0.125 100	V 0.125 100	0 125 100	200	ERA3VPB	±0.1	±15													
(0603)		100	200	ERA3VRB	±0.1	+10	1 k to 100 k	(E24, E96)												
			ERA3VRW	±0.05	10															
ERA3K (0603)	0.125	100	200	ERA3KEB	±0.1	±25	102 k to 240 k	(E24, E96)												
					ERA6VEB	±0.1	±25	47 to 100 k	(E24, E96)											
ERA6V	0.25	150	200	ERA6VPB	±0.1	±15	1 k to 100 k (E24, E		-55 to +155	Crada 0										
(0805)	0.25	150	300	ERA6VRB	±0.1	+10		(E24, E96)		Grade 0										
				ERA6VRW	±0.05	110														
ERA6K (0805)	0.25	150	300	ERA6KEB	±0.1	±25	102 k to 750 k	(E24, E96)												
				ERA8VEB		±25	47 to 100 k	(E24, E96)												
ERA8V	0.25	200	400	ERA8VPB	±0.1	±15	1 k to 100 l	< (E24, E96)												
(1206)	0.25	200	400	ERA8VRB		+10	1 k to 100 l	(E24 E96)												
-				ERA8VRW	±0.05	±10	1 K to 100 i	(L24, L90)												
		25 200		ERA8KEB	±0.1	±25	102 k to 1 M	A (E24 E96)	_											
ERA8K	0.25		400	ERA8KPB		±15	102 K to 1 I	4 (L24, L90)												
(1206)	0.25	200	700	ERA8KRB		+10	102 k to 160	k (E24 E96)												
														ERA8KRW	±0.05	- 10	102 K (0 100	12 K LO 100 K (E24, E96)		

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) × RCWV or Maximum Overload Voltage listed above, whichever less.

*4: E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.

*5: Expanded resistance range

Power derating curve

For resistors operated in ambient temperatures above 85°C, power rating shall be derated in accordance with the figure on the right.





Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

Thin Film Chip Resistors, High Stability and Reliability Type

Dimensions (not to scale)



						Unit : mm		
Part No.	Dimensions							
	L	W	а	b	Т	(g/1000 pcs)		
ERA2V	1.00±0.05	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.35±0.05	0.6		
ERA3V,3K	1.60±0.15	0.80±0.10	0.30±0.20	0.30±0.20	0.45±0.10	2		
ERA6V,6K	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.55±0.10	5		
ERA8V,8K	3.20±0.20	1.60±0.10	0.50±0.20	0.50±0.20	0.55±0.10	10		

Performance

Toot Itom	Performance	Tost conditions			
rest item	requirements ⊿R				
Resistance	Within specified	20 °C			
	tolerance	20 0			
T. C. R.	Within specified	+25 ℃ / +125 ℃			
	1. C. R.				
Overload	±0.1 %	Rated voltage× 2.5, 5 s			
Resistance to	±0.1 %	270 °C, 10 s			
soldening neat					
Rapid change of temperature	±0.1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.),1000 cycles			
High temperature		-			
exposure	±0.1 %	+155°C, 1000 h			
Damp heat,	+0 1 %				
Steady state	±0.1 70	05 C, 05 %KH, 1000 II			
Lood life in humidity	+0 1 %	85 ℃, 85 %RH, 10 % of Rated power ^{*1} ,			
Load life in numberly	±0.1 70	1.5 h ON / 0.5 h OFF cycle , 1000 h			
Endurance at 85℃	±0.1 %	85 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			
		ΔEC 0200 002 : 150 pF, 2000 Ω, positive 5 times,			
		negative 5 times			
Electro static	· • • • • · * ?	ERA2V : 1.0 kV (Class 1c)			
discharge (HBM)	±0.1 % ²	ERA3V(3K) : 1.5 kV (Class 1c)			
		ERA6V(6K) : 2.0 kV (Class 2)			
		ERA8V(8K) : 2.0 kV (Class 2)			

*1: Applied Voltage is " $\sqrt{0.1 \times \text{Power Rating} \times \text{Resistance Values}}$ ", or "Limiting Element Voltage×0.316", whichever less.

*2: Depends on resistance value.

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INDUSTRY

Metal Film (Thin Film) Chip Resistors, High Reliability Type



ERA A type ERA 1A, 2A, 3A, 6A, 8A series

Features

- High reliability
- : Stable at high temperature and humidity
- (85 $^{\circ}$ C 85 $^{\circ}$ RH rated load, Category temperature range : –55 $^{\circ}$ C to +155 $^{\circ}$ C)
- : Low resistance tolerance and Temperature Coefficient of Resistance
- High accuracyHigh performance
- : Low current noise, excellent linearity
- Reference standard
- AEC-Q200 compliant
 RoHS compliant
- : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C
- As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

E24 series



• E96 series and other Resistance values



Note : Duplicated resistance values as E24 series part umbers shall follow E24 part numbers. (apply three digit resistance value)

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use Should a safety concern arise regarding this product, please be sure to contact us immediately. ERA8A

Metal Film (Thin Film) Chip Resistors, High Reliability Type

Rating	S									
Part No. (inch size)	Power rating ^{*1} (85 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Part No. (detail)	Resistance tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Resista range (Ω)	ance *4 *5	Category temperature range (℃)	AEC-Q200 Grade
				ERA1AEB	±0.1	±25	100 to 10 k	(E24,E96)		
ERA1A				ERA1AEC	±0.25			(
(0201)	0.05	25	50	ERA1ARC	±0.25		100 to 10 k	(E24,E96)		
			ERA1ARB	±0.1	±10					
				ERA1ARW	±0.05		1 k to 10 k	(E24,E96)		
				ERA2AKD	±0.5	±100	10 to 46.4	(E24,E96)		
				ERA2AED	±0.5	~-		<i>.</i>		Grade 1
				ERA2AEC	±0.25	±25	47 to 100 K (E24,E96)			
ERA2A	0.063	50	100	ERA2AEB	±0.1					
(0402)				ERA2APC	±0.25	±15	200 to 47 k (E24,E96)	(E24,E96)		
				ERA2APB	±0.1			· · · /		
				ERA2ARC	±0.25	±10	200 to 47 k	(E24.E96)		
				ERA2ARB	±0.1	. 50		(, ,		
FRA3A			ERA3AHD	±0.5	±50	10 to 46.4	(E24,E96)			
				ERA3AED	±0.5					
				ERA3AEC	±0.25	±25	47 to 330 k	(E24,E96)		
				ERA3AEB	±0.1					
(0603)	0.1	75	150	ERA3APC	±0.25	±15	470 to 100 k	(E24,E96)		
(<i>)</i>				ERA3APB	±0.1			(<i>'</i> , <i>'</i> ,		
				ERA3ARC	±0.25	±10		<i>.</i>	-55 to +155	
				ERA3ARB	±0.1		1 k to 100 k	(E24,E96)		
				ERA3ARW	±0.05			(=0, =00)		
				ERA6AHD	±0.5	±50	10 to 46.4	(E24,E96)		
				ERA6AED	±0.5					
				ERA6AEC	±0.25	±25	47 to 1 M	(E24,E96)		
ERA6A				ERA6AEB	±0.1					
(0805)	0.125	100	200	ERA6APC	±0.25	±15	470 to 100 k	(E24,E96)		Grade 0
(<i>)</i>				ERA6APB	±0.1			· · · /		
				ERA6ARC	±0.25			<i>.</i>		
				ERA6ARB	±0.1	±10	1 k to 100 k	(E24,E96)		
				ERA6ARW	±0.05					
				ERA8AHD	±0.5	±50	10 to 46.4	(E24,E96)		
				ERA8AED	±0.5					
				ERA8AEC	±0.25	±25	47 to 1 M	(E24,E96)		
FRA8A				ERA8AEB	±0.1					
(1206)	0.25	150	150 300	ERA8APC	±0.25	+15	470 to 100 k	(E24,E96)		
· /				ERA8APB	±0.1	±10		(227,200)		
				ERA8ARC	±0.25			k (E24,E96)		
				ERA8ARB	±0.1	±10) 1 k to 100 k			
				ERA8ARW	±0.05					

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) × RCWV or Maximum Overload Voltage listed above, whichever less.

*4: E192 series resistance values are also available. Please contact us for details.

*5: Duplicated resistance values between E96, E192 and E24 series shall follow E24 Part Numbers. (apply three digit resistance value)

Power derating curve

For resistors operated in ambient temperatures above 85 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

Metal Film (Thin Film) Chip Resistors, High Reliability Type



*0201/0402 size or E96 series do not have value markings.

Dimensions (not to scale)



						Unit : mm			
Part No.	Dimensions								
	L	W	а	b	Т	(g/1000 pcs)			
ERA1A	0.60±0.03	0.30±0.03	0.15±0.05	0.15±0.05	0.23±0.03	0.14			
ERA2A	1.00±0.10	0.50+0.10/-0.05	0.15±0.10	0.25±0.10	0.35±0.05	0.6			
ERA3A	1.60±0.20	0.80±0.20	0.30±0.20	0.30±0.20	0.45±0.10	2			
ERA6A	2.00±0.20	1.25±0.10	0.40±0.25	0.40±0.25	0.50±0.10	4			
ERA8A	3.20±0.20	1.60+0.05/-0.15	0.50±0.25	0.50±0.25	0.60±0.10	8			

Performance

Toot Itom	Performance	Test conditions		
restitem	requirements ⊿R	Test conditions		
Desistance	Within specified			
Resistance	tolerance	20 C		
тор	Within specified			
I. C. R.	T. C. R.	+25 C7+125 C		
Overload	R<47 Ω : ±0.5 %	Poted voltage x 2 5 5 s		
	R≧47Ω : ±0.1 %	Raleu Voltage X 2.3, 3 S		
Resistance to	R<47 Ω : ±0.5 %	270 °C 10 c		
soldering heat	R≧47Ω : ±0.1 %	270 C, 10 S		
Rapid change of temperature	R<47 Ω : ±0.5 %	ERA1A, 2A:–55 ℃ (30 min.) / +125 ℃ (30 min.),1000 cycles		
	R≧47Ω : ±0.1 %	ERA3A, 6A, 8A:–55 ℃ (30 min.) / +155 ℃ (30 min.),1000 cycles		
High temperature	R<47 Ω : ±0.5 %	+155 °C 1000 h		
exposure	R≧47Ω : ±0.1 %	+155 C, 1000 H		
Damp heat,	R<47 Ω : ±0.5 %			
Steady state	R≧47Ω : ±0.1 %	05 C, 05 %RH, 1000 II		
Load life in	R<47 0 · +0 5 %	85 $^\circ$, 85%RH, 10% rated power, 1.5 h ON / 0.5 h OFF cycle, 1000 h,		
Load me m		Max. test voltage : ERA2A : 15.8 V, ERA3A : 23.7 V, ERA6A : 31.6 V,		
numiaity	R≦4/Ω∶±0.1 %	ERA8A : 47.4 V		
	R<47 Ω : ±0.5 %			
Endurance at 85 C	R≧47Ω : ±0.1 %	85 C, Rated voltage, 1.5 n ON / 0.5 h OFF cycle, 1000 h		

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

High Precision Thick Film Chip Resistors

ERJ PB type

anasor



ERJ PB3, PB6 series

Features

- Achieve the resistance tolerance ±0.1 % with high reliability metal glaze thick film resistor
- Guarantee the temperature coefficient of Resistance ±50×10⁻⁶/K in high resistance range up to 1 MΩ
- High power : 0.20 W : 0603 inch /1608 mm size(ERJPB3)
 - : 0.25 W : 0805 inch /2012 mm size(ERJPB6)
- Reference Standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{⁺3} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJPB3 (0603)	0.20	150	200	±0.1 ±0.5	200 to 100 k (E24, E96)	±50	55 to +155	Grade 0
ERJPB6 (0805)	0.25	150	200	±0.1 ±0.5	200 to 1 M (E24, E96)	±50	-00 10 + 100	Grade 0

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum overload voltage listed above, whichever less.

Power derating curve

For resistors operated in ambient temperatures

Should a safety concern arise regarding this product, please be sure to contact us immediately.

above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



High Precision Thick Film Chip Resistors

Construction



Dimensions (not to scale)



Unit : mm

Part No.	Dimensions								
	L	W	а	b	Т	(g/1000 pcs)			
ERJPB3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2			
ERJPB6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			

Performance

Test Item	Performance requirements ⊿R	Test conditions			
Resistance	tolerance	20 °C			
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C			
Overload	±0.5 %	Rated voltage× 2.0, 5 s			
Resistance to soldering heat	±0.5 %	270 °C, 10 s			
Rapid change of temperature	±0.5 %	–55 ℃ (30 min.) / +155 ℃ (30 min.),100 cycles			
High temperature exposure	±0.5 %	+155 ℃, 1000 h			
Damp heat, Steady state	±0.5 %	60 ℃, 90 % to 95 %RH, 1000 h			
Load life in humidity	+0 5 %	60 ℃, 90 % to 95 %RH, Rated voltage,			
Load me in numbuly	±0.0 %	1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 ℃	±0.5 %	70 $^\circ C$, Rated voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h			

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without house, just leave, just Should a safety concern arise regarding this product, please be sure to contact us immediately. 21

Panasonic

INDUSTRY

Thick Film Chip Resistors

(Low Resistance Type)

ERJ type

ERJ 2LW, 3LW, 6LW series

BIO EDV

ERJ 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series

ERJ 2BS/Q, 3BS/Q, 6DS/Q, 6BS/Q, 8BS/Q, 14BS/Q series ERJ 3RS/Q, 6RS/Q, 8RS/Q, 14RS/Q, 12RS/Q, 12ZS/Q, 1TRS/Q series ERJ L03, L06, L08, L14, L12, L1D series

Features

- Current sensing resistor
- Small size and lightweight
- Realize both low-resistance & High-precision by original thick film resistive element & special electrode structure
- Suitable for both reflow and flow soldering
- Realize High-power by double-sided resistive elements structure that aimed to suppress temperature rising
 - : ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW
- Low TCR
- : ±75×10⁻⁶/K(ERJ6CW, ERJ8CW)
- Low resistance value \Box : Thick film resistors available from 5 m Ω (ERJ3LW, 6LW)
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2144
- AEC-Q200 compliant (Please contact us for automotive of ERJ*CW/LW)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJ 2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series
 < High power (double-sided resistive elements structure) type>



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.



Ratings

<High power (double-sided resistive elements structure) type>

Part No. (inch size)	Power rating (70 ℃) ^{*1} (W)	Resistance tolerance (%)	Resistance range ^{*2} (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade	
ERJ2LW (0402)	0.2	±1, ±2, ±5	10 m	0 to +500			
ER 131 W (0603)	0.25	+1 +2 +5	5 m	0 to +700	-55 to +125	Grade 1	
	0.25	1, 12, 10	10 m	0 to +300	-33 10 1 123	Grade 1	
ERJ6LW (0805)	0.5	±1, ±2, ±5	5, 6, 7, 8, 9 m	0 to +300			
ERJ2BW (0402)	0.25	±1, ±2, ±5	47 m to 100 m (E24)	0 to +300			
ER 13BW/ (0603)	0.33	0.33	33 +1 +2 +5	20 m to 100 m (E24)	$20 \text{ m}\Omega \leq \text{R} \leq 39 \text{ m}\Omega$:0 to +250		
E1(05000 (0005)	0.00	1, 12, 10	201110100111 (L24)	39 m $\Omega \leq R \leq$ 100 m Ω $^{:0}$ to +150			
ER (6BW/ (0805)	0.5	+1 +2 +5	10 m to 100 m (E24)	10 m $\Omega \leq$ R < 15 m Ω :0 to +300	55 to +155	Crada 0	
LI(30DW (0003)	0.5	1, 12, 10	10 111 (0 100 111 (024)	$15 \text{ m}\Omega \leq R \leq 100 \text{ m}\Omega^{-:0 \text{ to } +200}$	-33 10 1 133	Grade 0	
				$10 \text{ m}\Omega \leq \text{R} \leq 20 \text{ m}\Omega$:0 to +200			
ERJ8BW (1206)	1	±1, ±2, ±5	10 m to 100 m (E24)	20 m $\Omega \le R \le 47$ m Ω :0 to +150			
				47 m $\Omega \le R \le 100$ m Ω ^{:0 to +100}			
ERJ6CW (0805)	0.5	±0.5, ±1, ±2, ±5	10 m to 30 m (E24)	±75	55 to +125	Crada 1	
ERJ8CW (1206)	1	±1, ±2, ±5	10 m to 50 m (E24)	±75	-55 10 +125	Giade I	

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Please contact us when resistors of irregular series are needed.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value.

Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

Ratings

<High power type>

Part No. (inch size)	Power rating (70 ℃) ^{*1} (W)	Resistance tolerance (%)	Resistand range ^{*3} (Ω)	ce	T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ2BS (0402)	0 166	±1 ±2 ±5	0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +300 $$		
ERJ2BQ (0402)	0.100	1, 12, 13	0.22 to 1.0	(E24)	$0.22~\Omega \leq R \leq 1.0~\Omega$ $$: 0 to +250		
ERJ3BS (0603)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R \le 0.22 \ \Omega : 0 \text{ to } +300$		
	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \ \Omega \le R \le 1.0 \ \Omega \ : 0 \text{ to } +300$		
ERJ3BQ (0003)				(E24)	$1.0 \ \Omega \le R \le 9.1 \ \Omega$: ±200		
ERJ6DS (0805)			0.10 to 0.20	(E24 ^{*2})	$0.10 \ \Omega \le R \le 0.22 \ \Omega : 0 \text{ to } +150$		
	0.5	±0.5, ±1, ±2, ±5	0.22 to 0.1	(F0 4 ^{*2})	$0.22 \ \Omega \le R \le 1.0 \ \Omega \ : 0 \text{ to } +100$		
EKJODQ (0003)))		0.22 10 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 100$		
ERJ6BS (0805)			0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +250 $$	–55 to +155	Grade 0
	0.33	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +250		
EKJOBQ (0003)			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 200$		
ERJ8BS (1206)			0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +250 $$		
	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +250		
ERJODQ (1200)			1.0 to 9.1	(E24)	$1.0 \ \Omega \le R \le 9.1 \ \Omega \ : \pm 200$		
ERJ14BS (1210)			0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +200 $$		
EB 114PO (1210)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +200 $$		
ERJ14DQ(1210)			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 100$		

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: E96 series resistance values are also available. Please contact us for details.

*3: Please contact us when resistors of irregular series are needed.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value.

• Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

<Standard type>

Part No. (inch size)	Power rating (70 ℃) ^{*1} (W)	Resistance tolerance (%)	Resistance range ^{*2} (Ω)		Resistance range ^{*2} (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ3RS (0603)			0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +300 $$				
	0.1	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R$ < 1.0 Ω $$: 0 to +300 $$				
			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 200$				
ERJ6RS (0805)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R \le 0.22 \ \Omega : 0 \text{ to } +250$				
	0.125	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +250 $$				
			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 200$				
ERJ8RS (1206)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R \le 0.22 \ \Omega : 0 \text{ to } +250$				
	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +250				
ERJORQ (1200)			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 200$				
ERJ14RS (1210)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R \le 0.22 \ \Omega : 0 \text{ to } +200$				
EP 11/PO (1210)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \ \Omega \le R \le 1.0 \ \Omega \ : 0 \sim +200$	–55 to +155	Grade 0		
E(3) 4 (Q(12))			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 100$				
ERJ12RS (1812)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R \le 0.22 \ \Omega : 0 \text{ to } +200$				
EP 112PO (1812)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +200 $$				
			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 100$				
ERJ12ZS (2010)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R \le 0.22 \ \Omega : 0 \text{ to } +200$				
EB (1270 (2010)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \ \Omega \le R \le 1.0 \ \Omega \ : 0 \text{ to } +200$				
ERJ122Q (2010)			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 100$				
ERJ1TRS (2512)			0.10 to 0.20	(E24)	$0.10~\Omega \leq R < 0.22~\Omega$ $$: 0 to +200				
	1	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \leq R < 1.0~\Omega$ $$: 0 to +200 $$				
			1.0 to 9.1	(E24)	$1.0 \ \Omega \leq R \leq 9.1 \ \Omega \ : \pm 100$				

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Please contact us when resistors of irregular series are needed.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= / Power Rating × Resistance Value.

Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

Ratings

<Low TCR type>

Part No. (inch size)	Power rating (70 ℃) ^{*1} (W)	Resistance tolerance (%)	Resistance range ^{*2} (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJL03 (0603)	0.2	±1, ±5	47 m to 100 m	±200		
ERJL06 (0805)	0.25	±1, ±5	47 m to 100 m	±100		
ERJL08 (1206)	0.33	±1, ±5	47 m to 100 m	±100	55 to +125	Grade 1
ERJL14 (1210)	0.33	±1, ±5	20 m to 100 m	n to 100 m		Grade I
ERJL12 (1812)	0.5	±1, ±5	20 m to 100 m	$R < 47 \text{ m}\Omega \div \pm 300$ $R > 47 \text{ m}\Omega \div \pm 100$		
ERJL1D (2010)	0.5	±1, ±5	40 m to 100 m			

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Standard R.V. : 20 m Ω , 22 m Ω , 33 m Ω , 39 m Ω , 47 m Ω , 50 m Ω , 100 m Ω , Custom R.V. : Each 1 m Ω within upper range.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= / Power Rating × Resistance Value.

· Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions (not to scale)



Part No.			Dimensions		1	Mass (Weight) (Reference)
	L	W	а	b	Т	(g/1000 pcs)
ERJ2LW	1.00±0.10	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.40±0.05	0.8
ERJ2BW	1.00±0.10	0.50+0.10/-0.05	0.24±0.10	0.24±0.10	0.35±0.05	0.8
ERJ2B	1.00±0.10	0.50+0.10/-0.05	0.20±0.10	0.27±0.10	0.35±0.05	0.8
ERJ3LW (5 mΩ)	1.60±0.15	0.80±0.15	0.50±0.20	0.50±0.20	0.55±0.10	3
ERJ3LW (10 mΩ) ERJ3BW	1.60±0.15	0.80±0.15	0.40±0.20	0.40±0.20	0.55±0.10	3
ERJ3R ERJ3B ERJL03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2
ERJ6LW	2.00±0.20	1.25±0.20	0.63±0.20	0.63±0.20	0.70±0.10	6
ERJ6BW	2.00±0.20	1.25±0.20	0.55±0.20	0.55±0.20	0.65±0.10	6
ERJ6CW (10 to 13 mΩ)	ERJ6CW (10 to 13 mΩ)	1 20+0 20	0.60±0.20	0.60±0.20	0.65+0.10	6
ERJ6CW (15 to 30 mΩ)	2.05±0.20	1.30±0.20	0.45±0.20	0.45±0.20	0.05±0.10	0
ERJ6D	2.00±0.20	1.25±0.10	0.40±0.20	0.55±0.25	0.60±0.10	5
ERJ6R ERJ6B ERJL06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	5
ERJ8BW	3.20±0.20	1.60±0.20	1.00±0.20	1.00±0.20	0.65±0.10	13
ERJ8CW (10 to 16 mΩ)	3.20±0.20	1.60±0.20	1.10±0.20	1.10±0.20	0.65±0.10	13
ERJ8CW (18 to 50 mΩ)	3.20±0.20	1.60±0.20	0.60±0.20	0.60±0.20	0.65±0.10	13
ERJ8R ERJ8B ERJL08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10
ERJ14R ERJ14B ERJL14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16
ERJ12R ERJL12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27
ERJ12Z ERJL1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27
ERJ1TR	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45
					•	4

Design and specifications are each subject to change without house. For some of the second states, Should a safety concern arise regarding this product, please be sure to contact us immediately. Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Performance

• ERJ2 LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series <High power (double-sided resistive elements structure) type>

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	ERJ6LW : Rated voltag× 1.77, 5 s ERJ8BW (R > 0.05 Ω) : Rated voltag× 1.77, 5 s Other : Rated voltag× 2.0, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 % ERJ2LW : ±2 %	–55 ℃ (30min.) / +155 ℃ (ERJ□LW, ERJ□CW : +125 ℃) (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃ (ERJ□LW, ERJ□CW : +125 ℃), 1000 h
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

• ERJ 2BS/Q, 3BS/Q, 6BS/Q, 8BS/Q, 14BS/Q, 6DDS/Q, 3RS/Q, 6RS/Q, 8RS/Q, 14RS/Q, 12RS/Q, 12ZS/Q, 1TRS/Q series <High power type/Standard type>

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	Rated voltage× 2.5 (ERJ6D : ×1.77), 5 s
Resistance to soldering heat	±1 %	270 °C, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

ullet ERJ L03, L06, L08, L14, L12, L1D series < Low TCR type >

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±1 %	270 °C, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +125 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+125 ℃, 1000 h
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without notice, rock tasks, i.e. Should a safety concern arise regarding this product, please be sure to contact us immediately. 27





This series is not a recommended product. Not recommended for new design.

Current Sensing Resistors, Metal Plate Type

ERJ MS, MB type

ERJ MS4, MB1 series

Features

- Ideal for current sensing solution
- Small case size with high power
- Metal plate bonding technology. Excellent long term stability
- Outer Resin with high heat dissipation. Wide temperature range (-65 °C to +170 °C)
- AEC-Q200 compliant
- RoHS compliant
- ISO9001, ISO/TS16949 certified
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

U							
Part No. (inch size)	Power rating (70 ℃) (W)	Resistance range (mΩ)	Resistance tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	Terminal temp. upper limit (℃)	AEC-Q200 Grade
ERJMS4S (2512)	3	1, 2, 3, 4	F : ±1	±75		130	
ERJMS4H	3	5, 6	F : ±1	±75	65 to ±170		Crada
(2512)	2	7, 8, 9, 10	F : ±1	±75	-05 10 +170	100	Glade
ERJMB1S (1020)	2	1, 2, 3, 4, 5	F : ±1	±75		130	

* Please contact us when resistors of irregular series are needed.

Power derating curve

If the terminal temperature of the resistor is more

than terminal temperature upper limit value of the

rated table, please reduce the rated power according

to the Power Derating Curve shown in the figure on the right. <Supplemented>

In the case of the temperature measurement of the terminal portion of the resistor, Please perform under the following conditions.

1) Terminal temperature measurement, please apply the temperature of the higher of either the left or right electrode upper surface of the resistor.

2) Please measure the temperature of the resistor in the land pattern printed of circuit board and plan to use by real conditions



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

Current Sensing Resistors, Metal Plate Type



Dimensions in mm (not to scale), Recommended land pattern



• ERJMB1S



Unit : mm

Part No.		Dime	Recom	Mass (Weight) (Reference)				
	L	W	A	Т	а	b	с	(g/1000 pcs)
ERJMS4S	6.40±0.25	3.20±0.25	2.20±0.25	1.20±0.15	2.7	3.4	2.0	120
ERJMS4H	6.40±0.25	3.20±0.25	1.25±0.25	1.20±0.15	1.7	3.4	4.0	115
ERJMB1S	2.55±0.25	5.00±0.25	0.68 +0.15/-0.20	0.90±0.15	1.15	5.5	1.1	40



Long-term stability



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Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Maximum pulse energy respectively pulse power for continuous operation

Referance Data

Condition : Room Temperature, OFF : 10 s, 1000 cycle, Wave form : Square Change of Resistance = ± 1 %

ERJMS4S/ERJMS4H



• ERJMB1S



Current Sensing Resistors, Metal Plate Type

Performance (AEC-Q200)

• ERJMS4S/ERJMS4H

Test item	Performance requirements ⊿R	Typical value ⊿R	Test condition
Thermal shock	±1 %	0.20 %	–55 ℃ /+155 ℃,1000 cycles
Overload	±0.5 %	0.10 %	Rated power x 3, 5 s
Solderability	> 95% coverage	> 95% coverage	245 ℃, 3 s
Resistance to solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low temperature storage and operation	±0.5 %	0.03 %	–65 ℃, 24 h
Resistance to soldering heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 ℃, 10 s)
Moisture resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 ℃, Rated Power, 2000 h
Storage life at elevated temperature	±1 %	0.30 %	170 ℃, 2000 h
High temperature characteristics	±0.5 %	0.05 %	140 ℃, 2000 h
Frequency characteristics	< 5 nH	< 2 nH	Inductance

• ERJMB1

Test item	Performance requirements ⊿R	Typical value ⊿R	Test condition
Thermal shock	±1 %	0.30 %	–55 ℃ /+155 ℃,1000 cycles
Overload	±1 %	0.30 %	Rated power x 2.5, 5 s
Solderability	> 95% coverage	> 95% coverage	245 ℃, 3 s
Resistance to solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low temperature storage and operation	±0.5 %	0.03 %	–65 ℃, 24 h
Resistance to soldering heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 ℃, 10 s)
Moisture resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 ℃, Rated Power, 2000 h
Storage life at elevated temperature	±1 %	0.30 %	170 ℃, 2000 h
High temperature characteristics	±0.5 %	0.05 %	140 ℃, 2000 h
Frequency characteristics	< 5 nH	< 2 nH	Inductance

Temperature rise





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INDUSTRY

High Power Chip Resistors (Wide Terminal Type) ERJ A, B type

ERJ A1, B1, B2, B3 series

Features

- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

•R015 0.015Ω=15 mΩ R10 R10





High Power Chip Resistors (Wide Terminal Type)

Part No. (inch size)	Power rating ^{*1} (W)	Rated ambient temperature ^{*2} (℃)	Rated terminal part temperature ^{*2} (℃)	Limiting element voltage ^{*3} (V)	Maximum overload voltage ^{*4} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJA1 (1225)	1.33	70	-	200	400	±1	100m to 10k (E24)	±100		Grade 0
						±2, ±5	10m to 10k (E24)	10mΩ≤R<100mΩ : ±350 100mΩ≤R≤10kΩ : ±200		
ERJB1 (1020)	2 (R≤10Ω)	70	125	200	400	±1	10m to 10 (E24)	±1 % : 10mΩ≤R<22mΩ : 0 to +350		
						±2, ±5		22mΩ≤R<47mΩ ∶ 0 to +200		
								$47m\Omega \le R \le 100m\Omega : 0$ to ± 150		
								100mΩ≤R≤10kΩ ∶±100		
	1 (R>10Ω)	70	95			±1 ±2, ±5	11 to 10k (E24)	±2 %, ±5 % :		
								$10m\Omega \le R < 22m\Omega : 0 \text{ to } +350$		
								$22m\Omega \le R < 100m\Omega : 0 \text{ to } +200$		
	15			200	400	+1	10m to 1k (E24)	10000231310002 . 1200		
ERJB2 (0612)	(R≤1kΩ)	-	125			±2, ±5		±1%:		
	0.75					±1	1.1k to 1M	10mΩ≤R<22mΩ ∶ 0 to +300		
	(R>1kΩ)	-	90			±2, ±5	(E24)	22mΩ≤R<47mΩ ∶ 0 to +200		
	1 (R≤10Ω)	70	-			±1	10m to 10	47mΩ≤R<100mΩ ∶ 0 to +150		
						±2	(E24) 5, 6, 7, 8, 9,10m to 10 (E24) 11 to 1M (E24)	100mΩ≤R≤220mΩ ∶ 0 to +100		
						±5		220mΩ≤R≤1MΩ :±100		
								±2 %, ±5 % :		
								$5m\Omega \le R < 22m\Omega : 0 \text{ to } +300$		
								$22m\Omega \le R < 47m\Omega : 0 \text{ to } +200$		
								$471102 \le R < 1001102 : 0 to +130$ 100mO < R < 220mO : 0 to +200		
	0.75					±1		220mΩ≤R≤1MΩ : ±200		
	(R>10Ω)	70				±2, ±5				
ERJB3 (0508)	1	-	105	150	200	±1	20m to 10 (E24)	±1%:		
						+2 +5		$20m\Omega \le R \le 47m\Omega : 0 \text{ to } \pm 300$		
						,		47mΩ≤R<1Ω ∶ 0 to +200		
	0.5 (R≤1Ω)	70	-			±1	20m to 1 (E24)	1Ω≤R≤10Ω : ±100		
						±2, ±5		$\pm 2 \%, \pm 5 \%$: 20mΩ≤R<47mΩ : 0 to +300		
	0.33 (R>1Ω) 7	70	-			±1	1.1 to 10	47mΩ≤R<1Ω : 0 to +200		
		70				±2, ±5	(E24)	1Ω≤R≤10Ω ∶±200		

*1: Use it on the condition that the case temperature is below the upper category temperature.

Ratings

*2: If there is a doubt whether the rated ambient temperature or the rated terminal part temperature is used, give priority to the rated terminal part temperature.

- *3: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- *4: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Ratings

Power derating curve

• For resistors operated in ambient rated ambient temperature, power rating shall be derated in accordance with the figure below.

In addition, please use under the condition that the product temperature is below the upper category temperature.



•For resistors operated in ambient rated terminal part temperature, power rating shall be derated in accordance with the figure below.

In addition, please use under the condition that the product temperature is below the upper category temperature.



Construction (Example : ERJA1 type)


High Power Chip Resistors (Wide Terminal Type)

Dimensions (not to scale)



						Unit : mm		
Devit Nie	Dimensions							
Part No.	L	W	A ₁	B ₁	Т	(Reference)		
	3 20+0 20	6 40+0 20	0 70+0 20	0 45+0 20	0 55+0 10	(9,1000 p00)		
ERJA1	A.	B ₀	P	øD	C.	40		
	0.70+0.20	1 25+0 15	1 27+0 10	0.30+0.10/-0.20	0.4 min	10		
	0.70±0.20	1.25±0.15	1.21±0.10	0.00+0.10/-0.20	0. 4 mm.			



Part No	Dimensions							
Part No.	L	W	а	b	Т	(g/1000 pcs)		
ERJB1	2.50±0.20	5.00±0.20	0.25±0.20	0.90±0.20	0.55±0.20	27		







Unit : mm Part No. Dimensions Mass (Weight) (Reference) (g/1000 pcs) ERJB2 W Т L а b 0.30±0.20 0.65±0.15 5 mΩ≤R<10 mΩ 0.30±0.20 10 mΩ≤R<220 mΩ 1.60±0.15 3.20±0.20 11 0.50±0.20 0.55±0.15 220 mΩ≤R≤1 MΩ 0.25±0.20



						Unit : mn		
Part No.	Dimensions							
	L	W	а	b	Т	(g/1000 pcs)		
ERJB3	1.25±0.10	2.00±0.15	0.25±0.20	0.40±0.20	0.50±0.10	4.8		

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Should a safety concern arise regarding this product, please be sure to contact us immediately.

Unit : mm

High Power Chip Resistors (Wide Terminal Type)



Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	ERJA1, ERJB1 (1W) : Rated voltag x 2.5, 5 s ERJB2 (0.75 W) : Rated voltag x 2.2, 5 s ERJB1 (2 W), ERJB2 (1.5 W, 1 W), ERJB3 : Rated voltag x 2.0, 5 s
Resistance to soldering heat	±1 %	270°C, 10 s
Rapid change of temperature	±2 %	–55 ℃ (30 min.) / +125 ℃ (30 min.),1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity 1 (Applicable to rated ambient temperature-regulated products)	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage 1.5 h ON / 0.5 h OFF cycle, 1000 h
Load life in humidity 2 (Applicable to rated ambient temperature-regulated products)	±3 %	85 °C, 85 %RH, Rated power 10%, Continuously power, 1000 h
Durability at rated ambient temperature or rated terminal part temperature	±3 %	Rated ambient temperature or rated terminal part temperature, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

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Panasonic

INDUSTRY

Low TCR High Power Chip Resistors (Wide Terminal Type)



ERJ D type

ERJ D1, D2 series

Features

- Achieved High power and low TCR (±100×10⁻⁶/K) using wide terminal electrode structure and original material
- Suitable for small size/high power current detection (Low TCR enables high accuracy of current detection)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below. 1 2 6 8 9 10 11 12 Ε R J 1 F R 0 1 0 U D D Product code Resistance value Packaging methods Power Resistance Code inch Resistance value region rating tolerance Code Part No. Packaging Thick film Shown by 4 digits or chip resistors D1C $22 \text{ m}\Omega \leq R \leq 200 \text{ m}\Omega$ Code Tolerance letters Embossed carrier taping FR.ID1 1020 2 W υ 4 mm pitch, 5,000 pcs D1D $10 \text{ m}\Omega \leq R \leq 20 \text{ m}\Omega$ ±1 % (Ex.) F •R010: D2C 33 mΩ ≤R≤ 200 mΩ J ±5 % Punched carrier taping 0612 1 W v ERJD2 0.010 Ω=10 mΩ D2D 4 mm pitch, 5,000 pcs $10 \text{ m}\Omega \leq R \leq 30 \text{ m}\Omega$

Ratings

Part No. (inch size)	Power rating (70 ℃) ^{*1} (W)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJD1 (1020)	2	±1, ±5	10 m to 200 m (E24)	±100	55 to +155	Grada 0
ERJD2 (0612)	1	±1, ±5	10 m to 200 m (E24)	±100	-55 10 +155	Grade 0

*1: Use it on the condition that the case temperature is below the upper category temperature.

· Please contact us when resistors of irregular series are needed.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value.

Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV.

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

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Low TCR High Power Chip Resistors (Wide Terminal Type)



Dimensions (not to scale)





Unit : mm

Part No	Dimensions							
Part NO.	L	W	а	b	Т	(g/1000 pcs)		
ERJD1	2.50±0.20	5.00±0.20	0.30±0.20	0.90±0.20	0.60±0.20	27		
ERJD2	1.60±0.15	3.20±0.20	0.30±0.20	0.50±0.20	0.65±0.15	11		

Circuit configuration



Low TCR High Power Chip Resistors (Wide Terminal Type)

Performance		
Toot Itom	Performance	Test conditions
restitem	requirements ⊿R	
Posistanco	Within specified	20 °C
Resistance	tolerance	20 C
тор	Within specified	
1. C. K.	T. C. R.	+25 C7+125 C
Overload	±2 %	Rated voltag x 2.0, 5 s
Resistance to	±1 0/	270 °C 10 a
soldering heat	±1 70	270 C, 10 S
Rapid change of	+2 %	$EE \% (20 \text{ min}) (\pm 125 \% (20 \text{ min})) = 1000 \text{ avalage}$
temperature	12 70	-55 C (30 mm.) / +125 C (30 mm.), 1000 Cycles
High temperature	+1 %	±155 ℃ 1000 b
exposure	1 /0	+105 °C, 1000 II
Damp heat,	+1 %	60 °C 00 % to 05 % PH 1000 h
Steady state	170	
Lood life in humidity	12.0/	60 ℃, 90 % to 95 %RH, Rated voltage,
	IO 70	1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 $^\circ C$, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
	_0 /0	

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INDUSTRY

Anti-Surge Thick Film Chip Resistors ERJ P, PA,PM type ERJ PA2, PA3, P03, P06, P08, PM8, P14 series



Features

- ESD surge characteristics superior to standard metal film resistors
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power 0.20 W : 0603 inch / 1608 mm size (ERJP03)
 - 0.20 W : 0402 inch / 1005 mm size (ERJPA2)
 - 0.33 W : 0603 inch / 1608 mm size (ERJPA3)
 - 0.50 W : 0805 inch / 2012 mm size (ERJP06), 1210 inch / 3225 mm size (ERJP14)
 - 0.66 W : 1206 inch / 3216 mm size (ERJP08)
- High precision, High voltage, High resistance value (ERJPM8)

: Limiting element voltage 500 V, Resistance tolerance ±1 %, TCR ±100 (x 10⁻⁶ / K)

- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below. 10 11 12 Ε R J Ρ 1 0 2 0 6 D 0 V Nominal resistance value Product code Code inch size Resistance tolerance Packaging methods PA2 0402 Code Tolerance Code Packaging Part No. Thick film Three digit type (±5 %), chip resistors PA3 D ±0.5 % Four digit type (±1 %, ±0.5 %) Punched carrier Ttaping 0603 Х ERJPA2 Example: 2 mm pitch, 10,000 pcs F P03 +1 % 222 : 2.2 KΩ P06 0805 10R0 : 10 Ω J +5 % ERJPA3 1002 : 10 KΩ ERJP03 P08 Punched carrier taping 1206 V FR.IP06 4 mm pitch, 5,000 pcs PM8 ERJP08 ERJPM8 P14 1210 Embossed carrier taping U ERJP14 4 mm pitch, 5,000 pcs

Anti-Surge Thick Film Chip Resistors

Rating	S																		
Part No. (inch size)	Power rating ^{*1} (W)	Rated ambient temperature ^{*2} (℃)	Rated terminal part temperature ^{*2} (℃)	Limiting element voltage ^{*3} (V)	Maximum overload voltage ^{*4} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade									
						±0.5, ±1	10 to 1M (E24, E96)												
ERJPA2	0.20	70	-	50		±5	Resistance value expansion 1 to 1M (E24)	±0.5, ±1 : ±100		Grade 1									
(0402)						±0.5, ±1	10 to 1M (E24, E96)	R<10Ω : -100 to +600											
	0.25	-	100			±5	Resistance value expansion 1 to 1M (E24)												
	0.05	405				±0.5, ±1	10 to 1M (E24, E96)												
ERJPA3	0.25	105	-	450	200	±5	1 to 1.5M (E24)	±0.5, ±1 : ±100											
(0603)	0.00	0.33 -	130	150	200	±0.5, ±1	10 to 1M (E24, E96)	±5 : ±200											
	0.33					±5	1 to 1.5M (E24)												
		0.20 70													±0.5	10 to 1M (E24, E96)	±150	–55 to +155	
ERJP03 (0603)	0.20		70 -	150	200	±1	10 to 1M (E24, E96)	R<10Ω : –150 to +400											
						±5	1 to 1M (E24)	10Ω≤R ∶±200											
						±0.5, ±1	10 to 1M (E24, E96)	R<33Ω :±300 33Ω≤R :±100		Grade 0									
ERJP06 (0805)	0.50	70	115	400	600	±5	1 to 3.3M (E24)	R<10Ω : −100 to +600 10Ω≤R<33Ω : ±300 33Ω≤R : ±200											
ERJP08	0.66	70	125	500	1000	±0.5, ±1	10 to 1M (E24, E96)	±100											
(1206)	0.00	10	125	500	1000	±5	1 to 10M (E24)	R<10Ω ∶ −100 to +600 10Ω≤R ∶ ±200											
ERJPM8 (1206)	0.66	70	125	500	1000	±1	1.02M to 10M (E24, E96)	±100											
ERJP14	0.50	70	70 000	400	±0.5, ±1	10 to 1M (E24, E96)	±100												
(1210)	0.50	10	-	200	400	±5	1 to 1M (E24)	R<10Ω ∶ −100 to +600 10Ω≤R ∶ ±200											

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: If there is a doubt whether the rated ambient temperature or the rated terminal part temperature is used, give priority to the rated terminal part temperature.

*3: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*4: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Ratings

Power derating curve

•For resistors operated in ambient rated ambient temperature, power rating shall be derated in accordance with the figure below.

In addition, please use under the condition that the product temperature is below the upper category temperature.

% When the temperature of ERJP14 is 155 $^{\circ}$ C or less, the derating start temperature can be changed to 125 $^{\circ}$ C. (See the dotted line)



•For resistors operated in ambient rated terminal part temperature, power rating shall be derated in accordance with the figure below.

In addition, please use under the condition that the product temperature is below the upper category temperature.



Construction



Anti-Surge Thick Film Chip Resistors

Dimensions (not to scale)



b							
Part No			Dimensions			Mass (Weight)	
Fait NO.	L W a b T						
ERJPA2	1.00±0.05	0.50±0.05	0.20±0.15	0.25±0.10	0.35±0.05	0.8	
ERJPA3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2	
ERJP03	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.30±0.15	0.45±0.10	2	
ERJP06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4	
ERJP08,PM8	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10	
ERJP14	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16	

ESD Characteristic



Size (inch)	0402	0603, 0805, 1206, 1210
R	1.5 kΩ	R=0 Ω (\leq 1.5 kΩ) / 150 Ω > 1.5 kΩ)
С	100 pF	150 pF
E	±1 kV	±3 kV



Anti-Surge Thick Film Chip Resistors

60 ℃, 90 % to 95 %RH, Rated voltage,

1.5 h ON / 0.5 h OFF cycle, 1000 h

85 °C, 85 %RH, Rated power 10%,

Continuously power, 1000 h

Rated ambient temperature or rated terminal part temperature,

Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Periorinance			
Test Item	Performance requirements ⊿R	Test conditions	
Resistance	Within specified tolerance	20 °C	
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃ (ERJPA2 : +125 ℃)	
Overload	±2 %	ERJP06 : Rated voltag× 1.77, 5 s	
	Only when it is ERJP03 (D),	ERJPA2, ERJPA3, ERJP08, ERJPM8 : Rated voltag× 2.0, 5 s	
	P14 (D) : ±0.5 %	ERJP03, ERJP14 : Rated voltag× 2.5, 5 s	
Resistance to soldering heat	D:±0.5 %, F, J:±1 %	270 °C, 10 s	
Rapid change of temperature	±1 %	–55 ℃ (30min.) / +155 ℃ (ERJPA2 : +125 ℃) (30min.), 100 cycles	
High temperature exposure	±1 %	+155 ℃, 1000 h	
Damp heat,	±1 %	60 ℃, 90 % to 95 %RH, 1000 h	

±3 %

Only when it is ERJP03 (D),

P14 (D) : ±1 %

±3 %

±3 %

Only when it is ERJP03 (D),

P14 (D) : ±1 %

Daufar

Steady state Load life in

humidity 1

(Applicable to rated ambient temperature-regulated products)

Load life in

humidity 2

(Applicable to rated ambient temperature-regulated products) Durability at rated

ambient

temperature or rated

terminal part temperature







Anti-Surge Thick Film Chip Resistors (Double-sided resistive elements structure)

ERJ P W type

ERJ P6W series

Features

- ESD surge characteristics superior to standard metal film resistors
- Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power
- High pulse characteristics
- : 0.50 W, 2012(0805) size(ERJP6W)
- : 1.5 times higher than 0805 inch size Anti-Surge thick film chip resistors (ERJP06)
- Reference standards
- : IEC 60115-8、 JIS C 5201-8、 EIAJ RC-2134B
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Construction



Dimensions in mm (not to scale)



	a						
Туре		Mass (Weight)					
	L	W	а	Т	(g/1000 pcs)		
ERJP6W (0805)	2.00±0.20	1.25±0.20	0.35±0.20	0.65±0.10	6		

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change management of the sector of the s

Anti-Surge Thick Film Chip Resistors (Double-sided resistive elements structure)

Ratings							
Part No. (inch size)	Power rating ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3}	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (°C)
ERJP6W (0805) 0.5	0.5	5 150	200	± 1	10 to 1 M (E24,E96)	± 200	55 to +155
	0.5			+ 5	1 to 1 M	R < 10 Ω : -100 to +600	
				ΞЭ	(E24)	$10 \ \Omega \leq R : \pm 200$	

*1: Use it on the condition that the case temperature is below 155 $^\circ\!\! C.$

*2: Overload (Short-time Overload) test voltage (SOTV) shall be determined from SOTV=2.5 × Power rating or max. Over load voltage listed above whichever less.

*3: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=/Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



ESD Characteristic





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Anti-Pulse Thick Film Chip Resistors



ERJ T type ERJ T06, T08, T14 series ERJ T14L series

Features

- Anti-Pulse characteristics
 High pulse characteristics achieved by the optimized trimming specifications (ERJT06, T08, T14)
- Further high pulse characteristics achieved by trimming-less specifications (ERJT14L)
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power 0.25 W : 0805 inch /2012 mm size(ERJT06)
 - 0.33 W : 1206 inch /3216 mm size(ERJT08)
 - 0.50 W : 1210 inch /3225 mm size(ERJT14, ERJT14L)
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



* Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

Anti-Pulse Thick Film Chip Resistors

Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (*10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJT06 (0805)	0.25	150	200	±5	1 to 1 M (E24)	R<10 Ω : −100 to +600 10 Ω≤R<33 Ω : ±300 33 Ω≤R : ±200		
ERJT08 (1206)	0.33	200	400	±5	1 to 1 M (E24)	R<10 Ω ∶ −100 to +600 10 Ω≤R ∶ ±200	–55 to +155	Grade 0
ERJT14 (1210)	0.50	200	400	±5	1 to 1 M (E24)	R<10 Ω ∶ −100 to +600 10 Ω≤R ∶ ±200		
ERJT14L (1210)	0.50	200	400	±10 ±20	1 to 1 M (E12)	R<10 Ω ∶ −100 to +600 10 Ω≤R ∶ ±200		

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction Protective coating Flectrode (Inner) Electrode (Middle) Alumina substrate Thick film resistive element Electrode (Outer)

Dimensions (not to scale)



		b				Unit : mm			
Davit Nia	Dimensions								
Part No.	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERJT06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			
ERJT08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10			
ERJT14 ERJT14L	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16			

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Should a safety concern arise regarding this product, please be sure to contact us immediately.



Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +155 °C
Overload	±2 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃±3 ℃, 10 s ±1 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃ ±2 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃ ±2 ℃, 90 % to 95 %RH, Rated voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70℃	±3 %	70 ℃ ±2 ℃,Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

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INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors

ERJ S type (Au-based inner electrode type)

ERJ S02, S03, S06, S08, S14 series

ERJ S12, S1D, S1T series

ERJ U type (Ag-Pd-based inner electrode type)

ERJ U0X, U01, U02, U03, U06, U08, U14 series

ERJ U12, U1D, U1T, U6S, U6Q series



Features

- High resistance to sulfurization achieved by adopting an Au-based inner electrode (Series ERJS) and Aq-Pd-based inner electrode (Series ERJU)
- : Metal glaze thick film resistive element and three layers of electrodes High reliability
- Suitable for both reflow and flow soldering
- Low resistance type : ERJU6S, U6Q series : 0.1 Ω to 1 Ω
- : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C Reference standard
- AEC-Q200 compliant (except ERJU0X, ERJU01)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Code

U6

chip resistors

inch

0805

0 25 W

0

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below. ERJ S02 to ERJS1T, ERJU0X to ERJU1T series



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use Should a safety concern arise regarding this product, please be sure to contact us immediately

0.22 0 to 1.0

F

G

±1%

+2 %

±5 %

Shown by 3 digits

R20 : 0.20 Ω=200 mΩ 1R0 : 1.0 Ω=1000 mΩ

or letters.

(Fx)

FRJU6S

ERJU6Q

Punched carrier taping

4 mm pitch, 5,000 pc:

V

Anti-Sulfurated Thick Film Chip Resistors

Rating	S									
Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{⁺3} (V)	Resistance tolerance (%)	Resis rar (!	stance nge Ω)	T. (×1	C.R. 0 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJU0X (01005)	0.031	15	30	±1	10 to 1 M	(E24, E96)	R<10 Ω 10 Ω≤R<100 Ω 100 Ω≤R	: -100 to +600 : ±300 : +200	_55 to +125	_
ERJU01 (0201)	0.05	25	50	±1 ±5	10 to 1 M 1 to 1 M	(E24, E96) (E24)	R<10 Ω	: -100 to +600		
ERJS02 ERJU02 (0402)	0.1	50	100	±0.5, ±1 ±5	1 to 1 M ERJS02: 1 to ERJU02: 1 to	(E24, E96) 0 3.3 M 0 10 M (E24)	10 Ω to 1 MΩ 1 MΩ <r< td=""><td>: ±200 : -400 to +150</td><td></td><td></td></r<>	: ±200 : -400 to +150		
ERJS03 ERJU03 (0603)	0.1	75	150	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)			-	
ERJS06 ERJU06 (0805)	0.125	150	200	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)				
ERJS08 ERJU08 (1206)	0.25	200	400	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	R<10 Ω	: -100 to +600	EE to 14EE	Grada 0
ERJS14 ERJU14 (1210)	0.5	200	400	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	10 Ω to 1 MΩ	: ±200 (± 5 %) : ±100 (±0.5 %, ±1 %)	-55 10 + 155	Grade 0
ERJS12 ERJU12 (1812)	0.75	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	1 MΩ <r< td=""><td>: -400 to +150</td><td></td><td></td></r<>	: -400 to +150		
ERJS1D ERJU1D (2010)	0.75	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)				
ERJS1T ERJU1T (2512)	1.0	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)				

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value,

or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

[Low resistance type]

Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJU6S (0805)	0.25	±1 ±2 ±5	0.1 to 0.2 (E24	0 to ±150	55 to +155	Grado 0
ERJU6Q (0805)	0.25	11, 12, 15	0.22 to 1 (E24	010+150	-55 10 + 155	Grade 0

*1: Use it on the condition that the case temperature is below the upper category temperature.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=/Power Rating × Resistance Value.

Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

LFor jumperj

Part No.	Resistance	Rated current	Maximum overload current ^{*1}
ERJU0X		054	1 Δ
ERJU01		0.5 A	
ERJS02,ERJU02		1 A	2 4
ERJS03,ERJU03		IA	2 A
ERJS06,ERJU06	100 mQ or loop		
ERJS08,ERJU08	Too miss of less		
ERJS14,ERJU14		2 4	1 4
ERJS12,ERJU12	-	28	47
ERJS1D,ERJU1D			
ERJS1T,ERJU1T			

*1: Overload test current

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



Anti-Sulfurated Thick Film Chip Resistors

Construction



Dimensions (not to scale)



Unit : mm

Part No			Dimensions	Dimensions					
Fait NO.	L	W	а	b	Т	(g/1000 pcs)			
ERJU0X	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04			
ERJU01	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15			
ERJS02 ERJU02	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8			
ERJS03 ERJU03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJS06 ERJU06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4			
ERJU6	2.00±0.20	1.25±0.10	0.45±0.20	0.45±0.20	0.55±0.10	6			
ERJS08 ERJU08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
ERJS14 ERJU14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
ERJS12 ERJU12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27			
ERJS1D ERJU1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27			
ERJS1T ERJU1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without notice, risk desire, risk best, risk b

Anti-Sulfurated Thick Film Chip Resistors

Performance

• ERJ S02 to ERJS1T, ERJU0X to ERJU1T series

Testiters	Performance re	equirements ⊿R	Test conditions	
rest tiem	Resistor type	Jumper type	Test conditions	
Resistance	Within specified tolerance	100 m Ω or less	20 °C	
T. C. R.	Within Specified T. C. R.	200 m Ω or less	+25 ℃ / +155 ℃ (ERJU0X,U01 : +25 ℃ / +125 ℃)	
Overload	±2 %	100 m Ω or less	Rated voltage × 2.5, 5 s Jumper type : Max. overload current, 5 s	
Resistance to soldering heat	±1 %	100 m Ω or less	270 °C, 10 s	
Rapid change of temperature	±1 %	100 m Ω or less	–55 ℃ (30min.)/+155 ℃ (ERJU0X,U01 : +125 ℃) (30min.), 100 cycles	
High temperature exposure	±1 %	100 m Ω or less	+155 ℃ (ERJU0X,U01 : +125 ℃), 1000 h	
Damp heat, Steady state	±1 %	100 m Ω or less	60 ℃, 90 % to 95 %RH, 1000 h	
Load life in humidity	±3 %	100 m Ω or less	60 ℃, 90 % to 95 %RH, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h	
Endurance at 70 $^\circ \!$	±3 %	100 m Ω or less	70 ℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h	

• ERJ U6S, U6Q series

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±1 %	Rated voltage × 2.5, 5 s
Resistance to soldering heat	±1 %	270 °C, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +125 ℃ (30min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

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Panasonic INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors (Precision Type)



ERJ U R type (Ag-Pd-based inner electrode type) ERJ U2R, U3R, U6R series

Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode.
- High precision : Resistance tolerance : ± 0.5 %, TCR : $\pm 50 \times 10^{-6}$ /K
- High reliability : Metal glaze thick film resistive element and three layers of electrodes.
- Suitable for both reflow and flow soldering.
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJ U2R, U3R, U6R series



Ratings Power Limiting Maximum Category AEC-Resistance Part No. element overload Resistance range T.C.R. rating^{*1} temperature tolerance Q200 (inch size) (70 ℃) voltage^{*2} voltage^{*3} (Ω) $(\times 10^{-6}/K)$ range (%) Grade (°C) (W) (V)(V)ERJU2R 100 to 100 k 0.1 50 100 ±0.5 (E24, E96) (0402) ERJU3R 100 to 100 k 0.1 75 150 ±0.5 ± 50 -55 to +155 Grade 0 (E24, E96) (0603) ERJU6R 100 to 100 k 0.125 150 200 ± 0.5 (E24, E96) (0805)

*1 : Use it on the condition that the case temperature is below the upper category temperature.

*2 : Rated continuous working voltage (RCWV) shall be determined from RCWV= $\sqrt{Power rating \times Resistance value}$,

or limiting element voltage listed above, whichever less. *3 : Overload test voltage (OTV) shall be determined from OTV = Specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Anti-Sulfurated Thick Film Chip Resistors (Precsion Type)



Dimensions (not to scale)



					Unit : mm				
		Dimensions			Mass (Weight)				
L	VV	а	D	I	(g/1000 pcs)				
1 00+0 05	0 50+0 05	0 20+0 10	0 25+0 10	0 35+0 05	0.8				
1.00±0.00	0.00±0.00	0.20±0.10	0.20±0.10	0.00±0.00	0.0				
1.60+0.15	0.80+0.15/-0.05	0.30+0.20	0.30+0.15	0.45+0.10	2				
1.0020110	0.00 0.10 0.00	0.0010.20	0.0020.10	0.1020.10	-				
2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4				
	L 1.00±0.05 1.60±0.15 2.00±0.20	L W 1.00±0.05 0.50±0.05 1.60±0.15 0.80+0.15/-0.05 2.00±0.20 1.25±0.10	L W a 1.00±0.05 0.50±0.05 0.20±0.10 1.60±0.15 0.80+0.15/-0.05 0.30±0.20 2.00±0.20 1.25±0.10 0.40±0.20	L W a b 1.00±0.05 0.50±0.05 0.20±0.10 0.25±0.10 1.60±0.15 0.80+0.15/-0.05 0.30±0.20 0.30±0.15 2.00±0.20 1.25±0.10 0.40±0.20 0.40±0.20	L W a b T 1.00±0.05 0.50±0.05 0.20±0.10 0.25±0.10 0.35±0.05 1.60±0.15 0.80+0.15/-0.05 0.30±0.20 0.30±0.15 0.45±0.10 2.00±0.20 1.25±0.10 0.40±0.20 0.40±0.20 0.60±0.10				

Performance

Test Item	Performance requirements ⊿R	Test conditions		
Resistance	Within specified tolerance	20 °C		
T. C. R.	Within specified T. C. R.	+25 °C / +155 °C		
Overload	±2 %	Rated voltage × 2.5, 5 s		
Resistance to soldering heat	±1 %	270 °C, 10 s		
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles		
High temperature exposure	±1 %	+155 ℃, 1000 h		
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h		
Load life in humidity	±2 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 ℃	±2 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		

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INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)



ERJ UP type ERJ UP3, UP6, UP8 series

Features

- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure
- ESD surge characteristics superior to standard metal film resistors
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- 0.25 W: 0603 inch / 1608 mm size (ERJUP3) • High power
 - 0.50 W: 0805 inch / 2012 mm size (ERJUP6)
 - 0.66 W : 1206 inch / 3216 mm size (ERJUP8)
- : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C Reference standard
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

Part No. (inch size)	Power rating*1 (70 ℃) (W)	Limiting element voltage*2 (V)	Maximum overload voltage*3 (V)	Resistance tolerance (%)	Resis ran (۲	tance ige 2)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJUP3	0.25	150	200	±0.5, ±1	10 to 1 M	(E24, E96)	±100		
(0603)	0.25	150	200	±5	1 to 1.5 M	(E24)	±200	-	
50 11 10 0		400	600	±0.5, ±1	10 to 1 M	(E24, E96)	±100		
ERJUP6 (0805)	ERJUP6 0.50			15	1 to 2.2 M	(E24)	R<10 Ω : -100 to +600	55 to ±155	Grada 0
(0000)				±5	1 10 5.5 10	(L24)	10 Ω≤R ∶±200	-55 10 + 155	Glade 0
				±0.5, ±1	10 to 1 M	(E24, E96)	±100		
ERJUP8 0.66	500	1000	+5	1 to 10 M	(E24)	R<10 Ω : -100 to +600			
(1200)				τo			10 Ω≤R ∶±200		

*1: Use it on the condition that the case temperature is below the upper category temperature.

- *2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=/Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- *3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)

Ratings

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions in mm (not to scale)



						Unit : mm				
Part No	Dimensions									
Fall NO.	L	W	а	b	Т	(g/1000 pcs)				
ERJUP3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2				
ERJUP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4				
ERJUP8	3.20+0.05/-0.20	1.6+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10				

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)



Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +155 °C
Overlagd	10.0/	ERJUP6 : Rated voltag x 1.77, 5 s
Overload	±2 %	ERJUP3, ERJUP8 : Rated voltag x 2.0, 5 s
Resistance to soldering heat	D:±0.5 % F, J:±1 %	270 °C, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without notice, the subject to change without notice, the subject to contact us immediately. Should a safety concern arise regarding this product, please be sure to contact us immediately. 58

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Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)



ERJ C type

ERJ C1 series

Features

- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure (Covered electrode)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended applications

- Motor control circuit of the industrial equipment
- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃) (W)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJC1 (1020)	2	±1	10 m to 1 (E24)	$\begin{array}{l} 10 \ m\Omega \leq R < 22 \ m\Omega & : \ 0 \ to \ +350 \\ 22 \ m\Omega \leq R < 47 \ m\Omega & : \ 0 \ to \ +200 \\ 47 \ m\Omega \leq R < 100 \ m\Omega & : \ 0 \ to \ +150 \\ 100 \ m\Omega \leq R \leq 1 \ \Omega & : \ \pm100 \end{array}$	-55 to +155	Grade 0
(1020)		±5		$\begin{array}{l} 10 \ m\Omega \leq R < 22 \ m\Omega & : \ 0 \ to \ +350 \\ 22 \ m\Omega \leq R < 100 \ m\Omega & : \ 0 \ to \ +200 \\ 100 \ m\Omega \leq R \leq 1 \ \Omega & : \ \pm200 \end{array}$		

*1: Use it on the condition that the case temperature is below the upper category temperature.

• Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value.

· Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use Design and specifications are each subject to change minimation of the second state of

Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)

Ratings

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions (not to scale)



						Unit : mm			
Part No.	Dimensions								
	L	W	а	b	Т	(g/1000 pcs)			
ERJC1B	2 50±0 20	2 50+0 20 5 00+0 20		0 00+0 20	0 55+0 20	27			
ERJC1C	2.3010.20	5.0010.20	0.60±0.20	0.9010.20	0.3310.20	21			

Circuit configuration

ERJC1 series	

*6*0

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)

Performance					
Test Item	Performance requirements ⊿R	Test conditions			
Resistance	Within specified tolerance	20 °C			
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C			
Overload	±2 %	Rated voltage × 2.0, 5 s			
Resistance to soldering heat	±1 %	270 °C, 10 s			
Rapid change of temperature	±2 %	–55 ℃ (30 min.) / +125 ℃ (30 min.), 1000 cycles			
High temperature exposure	±1 %	+155 ℃, 1000 h			
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h			
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			

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High Temperature Thick Film Chip Resistor



(Automotive Grade) ERJH type

ERJ H2G, H2C, H2R, H3G series ERJ H3E, H3Q, H6G, HP6 series

Features

- High reliability : Metal glaze thick film resistive element and high temperature of electrodes structure
- ullet Achieve maximum category temperature 175 $^\circ\!\!C$ and rated category temperature 105 $^\circ\!\!C$
- Compatible with placement machines : Taping packaging available
- Suitable for both reflow and flow soldering
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

• ERJ H2G, H2C, H2R, H3G, H3E, H3Q, HP6 series : ±0.5 %, ±1 %, ±5 %



• ERJ H2G, H3G, H6G series : Jumper



High Temperature Thick Film Chip Resistor (Automotive Grade)

Ratings

[For Resistor]

Part No. (inch size)	Power rating*1 (105 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resist ran (Ω	Resistance T.C.R. range (×10 ⁻⁶ /K)		Category temperature range (℃)	AEC-Q200 Grade
ERJH2G (0402)	0.1	50	100	±5	1 to 300 k	(E24)	R < 10Ω : −100 to +600 10Ω ≤ R : ±200		
ERJH2C (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600		
ERJH2R (0402)	0.1	50	100	±0.5,±1	10 to 300 k	(E24,E96)	±100		
ERJH3G (0603)	0.125	75	150	±5	1 to 300 k	(E24)	R < 10Ω : −100 to +600 10Ω ≤ R : ±200		
ERJH3E (0603)	0.125	75	150	±0.5,±1	10 to 300 k	(E24,E96)	±100		Crada 0
ERJH3Q	0.25	_	_	±0.5,±1	1 to 9.76	(E24,E96)	+200	-55 10 + 175	Glade 0
(0603)	0.25	-	-	±5	1 to 9.1	(E24)	1200		
	0.5	400	600	+0.5	10 to 300 k	(E24 E96)	R < 33Ω : ±300		
	0.0	400	000	±0.0	10 10 500 K	(L24,L30)	$33\Omega \leq R : \pm 100$		
							R < 10Ω : –100 to +600		
ERJHP6	0.5	400	600	±1	1 to 300 k	(E24,E96)	$10\Omega \le R < 33\Omega : \pm 300$		
(0805)							$33\Omega \leq R : \pm 100$		
							R < 10Ω : –100 to +600		
	0.5	400	600	±5	1 to 300 k	(E24)	10Ω ≤R < 33Ω ∶ ±300		
							$33\Omega \leq R : \pm 100$		

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=/Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

[For Jumper]

Part No. (inch size)	Resistance	Rated current	Maximum overload current ^{*1}
ERJH2G (0402)	50 m Ω or less	1 A	2 A
ERJH3G (0603)		1 A	2 A
ERJH6G (0805)		2 A	4 A

*1: Overload test current

Power derating curve

For resistors operated in ambient temperatures above 105 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



Construction



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Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

High Temperature Thick Film Chip Resistor (Automotive Grade)

Dimensions (not to scale)



	Dimensions									
Part No.	L	W	а	b	Т	(Reference) (g/1000 pcs)				
ERJH2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8				
ERJH2C	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8				
ERJH2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8				
ERJH3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2				
ERJH3E	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2				
ERJH3Q	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2				
ERJH6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4				
ERJHP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4				

Performance

	- <i>i</i>				
Test item	Performance re	equirements ⊿R	Test conditions		
restitem	Resistor type Jumper type				
Resistance	Within specified tolerance	50 m Ω or less	20 °C		
T. C. R.	Within specified T. C. R.	50 m Ω or less	+25 °C / +175 °C		
Overload	±2 %	50 m Ω or less	ERJH2G, H2C, H2R, H3G, H3E, H3Q : Rated voltage× 2.5, 5 s ERJHP6 : Rated voltage× 1.77, 5 s Jumper type : Max. overload current, 5 s		
Resistance to soldering heat	±1 %	50 m Ω or less	270 ℃, 10 s		
Rapid change of temperature	±1 %	50 m Ω or less	–55 ℃ (30 min.) / +175 ℃ (30 min.), 1000 cycles		
High temperature exposure	±1 %	50 m Ω or less	+175 ℃, 1000 h		
Damp heat, Steady state	±1 %	50 m Ω or less	85 ℃, 85 %RH, 1000 h		
Load life in humidity	±3 %	50 m Ω or less	85 ℃, 85 %RH, Rated voltage (Jumper type :Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 105 ℃	±3 %	50 m Ω or less	105 ℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h		

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Chip Resistors Array

EXB type



EXB 14V, 18V, 24V, 28V, N8V, 2HV, series EXB 34V, V4V, 38V, V8V, S8V series

Features

High density

- 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size : EXB14V
- 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXB18V
- 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXB24V
- 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXB28V, N8V
- 8 resistors in 3.8 mm × 1.6 mm size / 1506 inch size : EXB2HV
- 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXB34V, V4V
- 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXB38V, V8V
- 4 resistors in 5.1 mm × 2.2 mm size / 2009 inch size : EXBS8V
- Improvement of placement efficiency Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor
- : IEC 60115-9, JIS C 5201-9, EIAJ RC-2129 • Reference Standard
- AEC-Q200 compliant (EXB2, EXB3)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Chip Resistors Array

Ratings

[For Resistor]

Part No. (inch size)	Power rating (70 ℃) (W/element)	Limiting element voltage ^{*1} (V)	Maximum overload voltage ^{⁺2} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
EXB14V (0201×2)	0.031	12.5	25	±5	10 to 1 M (E24)			
EXB18V (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M (E24)			-
EXB24V (0402×2)	0.063	50	100	±5	1 to 1 M (E24)			
EXB28V (0402×4)	0.063	50	100	±5	1 to 1 M (E24)			
EXB2HV (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M (E24)	R<10 Ω		Grade 1
EXB34V (0603×2)	0.063	50	100	±5	1 to 1 M (E24)	10 O to 1 MO	–55 to +125	
EXB38V (0603×4)	0.063	50	100	±5	1 to 1 M (E24)	: ±200		
EXBN8V (0402×4)	0.031	50	100	±5	10 to 1 M (E24)			
EXBV4V (0603×2)	0.063	50	100	±5	10 to 1 M (E24)			
EXBV8V (0603×4)	0.063	50	100	±5	10 to 1 M (E24)			-
EXBS8V (0805×4)	0.1	100	200	±5	10 to 1 M (E24)			

*1: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= Verver Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*2: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

[For Jumper]

Part No.	Resistance	Rated current	Maximum overload
EXB14V		0.5 A	1 A
EXB18V		0.5 A	1 A
EXB24V		1 A	2 A
EXB28V	-	1 A	2 A
EXB2HV		1 A	2 A
EXB34V	50 m Ω or less	1 A	2 A
EXB38V		1 A	2 A
EXBN8V		1 A	2 A
EXBV4V	- -	1 A	2 A
EXBV8V		1 A	2 A
EXBS8V		2 A	4 A

*1: Overload test current





Power derating curve



60 80 100 120 140 160 180

For resistors operated in ambient temperatures

Ambient temperature (°C)

0 20 40

-40 -20

Schematics Isolated type

0 -60



Chip Resistors Array

Dimensions (not to scale)

(1) Convex terminal type



EXB28V, 38V A_1 Б шţ П ს ≥ ш വ L P Т

I Init · mm

Part No.	Dimensions								
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)
EXB14V (0201×2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5
EXB24V (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10		0.18±0.10	(0.65)	0.25±0.10	1.2
EXB28V (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0
EXB2HV (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0
EXB34V (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5
EXB38V (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0
									() Reference

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(2) Concave terminal type





EXBN8V, V8V, S8V





									Unit : mm
Part No.				Dimer	nsions				Mass (Weight)
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)
EXBN8V (0402×4)	2.00±0.10	1.00±0.10	0.45±0.10	0.30±0.10	0.30±0.10	0.20±0.15	(0.50)	0.30±0.15	3.0
EXBV4V (0603×2)	1.60 +0.20/-0.10	1.60 +0.20/-0.10	0.60±0.10	0.60±0.10	_	0.30±0.15	(0.80)	0.45±0.15	5.0
EXBV8V (0603×4)	3.20 +0.20/-0.10	1.60 +0.20/-0.10	0.60±0.10	0.60±0.10	0.60±0.10	0.30±0.15	(0.80)	0.45±0.15	10
EXBS8V (0805×4)	5.08 +0.20/-0.10	2.20 +0.20/-0.10	0.70±0.20	0.80±0.15	0.80±0.15	0.50±0.15	(1.27)	0.55±0.15	30
									() Reference

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Dimensions (not to scale)

(3) Flat terminal type





Unit : mm

Part No.	Dimensions								
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)
EXB18V (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0

() Reference

Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltage x 2.5,5 s Jumper type:Max. overload current, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+125 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage (Jumper type :Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h

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Anti-Sulfurated Chip Resistors Array



EXB type EXB U14, U18, U24, U28 series EXB U2H, U34, U38 series

Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode
- High density
 - 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size : EXBU14
 - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXBU18
 - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXBU24
 - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXBU28
 - 8 resistors in 3.8 mm × 1.6 mm size / 1506 inch size : EXBU2H
 - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXBU34
 - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXBU38
- Improvement of placement efficiency
 Placement efficiency of chip resistor array is two, four or eight times of the flat type chip resistor
- Reference standard : IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 compliant (EXBU2, EXBU3)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Anti-Sulfurated Chip Resistors Array

Ratings

[For Resistor]

Part No. (inch size)	Power rating (70 ℃) (W/element)	Limiting element voltage ^{*1} (V)	Maximum overload voltage ^{*2} (V)	Resistance tolerance (%)	Resistar range (Ω)	nce	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
EXBU14 (0201×2)	0.031	12.5	25	±5	10 to 1 M	(E24)			
EXBU18 (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M	(E24)			_
EXBU24 (0402×2)	0.063	50	100	±5	1 to 1 M	(E24)	R<10 Ω	–55 to +125	
EXBU28 (0402×4)	0.063	50	100	±5	1 to 1 M	(E24)	10 O to 1 MO		
EXBU2H (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M	(E24)	: ±200		Grade 1
EXBU34 (0603×2)	0.063	50	100	±5	1 to 1 M	(E24)			
EXBU38 (0603×4)	0.063	50	100	±5	1 to 1 M	(E24)			

*1: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\/Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*2: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

[For Jumper]

Part No.	Resistance	Rated current	Maximum overload current ^{*1}
EXBU24			
EXBU28			
EXBU2H	100 m Ω or less	1 A	2 A
EXBU34			
EXBU38			
*1 0 1			

*1: Overload test current

Power derating curve

For resistors operated in ambient temperatures above 70°C, power rating shall be derated in accordance with the figure below.



Construction



Schematics

Isolated type



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change management of the second state of
Anti-Sulfurated Chip Resistors Array

Dimensions (not to scale)



EXBU28, U38





EXBU18 A_1 A_2 шţ <u>ш</u> P I





									Unit : mm			
Part No.	rt No. Dimensions											
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)			
EXBU14 (0201X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	—	0.15±0.10	(0.50)	0.15±0.10	0.5			
EXBU18 (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0			
EXBU24 (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	—	0.18±0.10	(0.65)	0.25±0.10	1.2			
EXBU28 (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0			
EXBU2H (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0			
EXBU34 (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5			
EXBU38 (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0			

() Reference

Performance		
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltage x 2.5,5 s Jumper type : Max. overload current, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +125 ℃ (30 min.),100 cycles
High temperature exposure	±1 %	+125 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70℃	±3 %	70℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h

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Chip Resistors Networks EXB type EXB D, E, A, Q series



Features

- High density placing for digital signal circuits
 - ·Bussed 8 or 15 resistors for pull up/down circuits
 - EXBD : 3.2 mm × 1.6 mm × 0.55 mm, 0.635 mm pitch
 - EXBE : 4.0 mm × 2.1 mm × 0.55 mm, 0.8 mm pitch
 - : 6.4 mm × 3.1 mm × 0.55 mm, 1.27 mm pitch EXBA
 - : 3.8 mm × 1.6 mm × 0.45 mm, 0.5 mm pitch EXBQ
 - ·Available direct placing on the bus line by means of half pitch spacing without through-holes on PWB ("High density placing" is shown below)
- High speed mounting using conventional placing machine
- Reference Standard : IEC 60115-9, JIS C 5201-9, EIAJ RC-2130
- RoHS compliant

[High density placing]



As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



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Chip Resistors Networks

Ratings

Part No.	Resistance range	Resistance	Number of	Number of	Power rating ^{*1}	Limiting element	Maximum overload	T.C.R.	Category temperature	AEC-Q200
(inch size)	(0)	(%)	terminals	resistors	(70 ℃)	voltage ²	voltage	(×10⁻⁰/K)	range	Grade
	(12)	(,,,,)			(W/element)	(V)	(V)		(°C)	
EXBD (1206)		+5		8 element	0.05 / element	25	50	±200		
EXBE (1608)	47 to 1 M (E12)		10 terminals		0.063 / element	25	50	±200	_55 to +125	_
EXBA (2512)		10			0.063 / element	50	100	±200		-
EXBQ (1506)	100 to 470 k (E6)		16 terminals	15 element	0.025 / element	25	50	±200		

*1: Use it on the condition that the case temperature is below the upper category temperature.

*2: Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

*3: Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Power derating curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction (Example : EXBD) Protective coating Protective coating Electrode (Inner) Alumina substrate Electrode (Outer) Thick film Thick film resistive element Alumina substrate Electrode resistive element Electrode (Middle) (Inner)

Circuit configuration



Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to change without nearest, should a safety concern arise regarding this product, please be sure to contact us immediately. 73

Chip Resistors Networks



	L	W	Т	A ₁	B ₁	A ₂	B ₂	(g/1000 pcs)			
	6.4±0.2	3.1±0.2	0.55±0.10	0.7±0.2	0.3±0.2	0.5±0.2	0.5±0.20]			
EXBA	Р	øD						40			
	1.27±0.10	0.3+0.1/-0.2									
	Dimensions										
Part No	Differisions										
Tarrio.	L	W	Т	A ₁	A ₂	A ₃	B ₁	(g/1000 pcs)			
	3.8±0.2	1.6±0.2	0.45±0.10	0.3±0.1	0.2±0.1	0.15+0.15/-0.05	0.15+0.15/-0.05				
EXBQ	B ₂	A ₄	B ₃	Р				9			
	0.25±0.15	0.15+0.20/-0.05	0.30±0.15	0.5±0.1							

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Design and specifications are each subject to charge without reaction and specifications are each subject to charge without reaction and the specification of the specification o

Chip Resistors Networks

Performance		
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 °C
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±3 %	Rated voltage x 2.5, 5 s
Resistance to soldering heat	±1 %	260 ℃ ±5 ℃, 5 s ±1 s
Rapid change of temperature	±2 %	–55 ℃ (30 min.) / +125 ℃ (30 min.),5 cycles
High temperature exposure	±3 %	+125 ℃, 100 h
Load life in humidity	±3 %	60 ℃±2 ℃, 90 % to 95 %RH, Rated power × 0.1, 1.5 h ON / 0.5 h OFF cycle, 500 h
Endurance at 70 ℃	±5 %	70 ℃±2 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

'anasoi INDUSTRY

Chip Attenuator EXB type



EXB 14AT, 24AT series

Features

- Unbalanced π type attenuator circuit in one chip EXB14AT (0.8 mm×0.6 mm), EXB24AT (1.0 mm×1.0 mm)
- Reduced mounting area

EXB14AT : About 60 % smaller than the area of an attenuator circuit consisting of three 0603 chip resistors, almost equal to the area of three 0402 chip resistors

EXB24AT : About 50 % smaller than the area of an attenuator circuit consisting of three 1005 chip resistors, almost equal to the area of three 0603 chip resistors

- Mounting cost reduction : (Only 1 chip placed as compared to 3)
- Attenuation : 1 dB to 10 dB

RoHS compliant

Recommended applications

- Attenuation / level control / impedance matching of high frequency (communication signalling equipment cellular phones(GSM, CDMA, PDC, etc.), PHS, PDAs)
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers Note : Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below. 7 1 2 3 5 6 8 9 10 12 4 11 Ε Х B 1 4 Α Т 3 R 3 Х Α Product code Dimensions and circuit Attenuation value Characteristics Tolerance Packaging methods Code configuration One-digit number /one impedance R3 ±0.3 dB Code Packaging Thick film (π type attenuator) letter shows 50 Ω R5 ±0.5 dB resistor Α Punched carrier taping networks 0.8 mm × 0.6 mm attenuation value Х 14AT 2 mm pitch, 10,000 pcs (inch size : 0302) (Ex.) 1.0 mm × 1.0 mm $1 \rightarrow 1 \text{ dB}$. A $\rightarrow 10 \text{ dB}$ 24AT (inch size : 0404)

Ratings	
Part No.	EXB14AT, EXB24AT
Attenuation value	1 dB, 2 dB, 3 dB, 4 dB, 5 dB, 6 dB, 10 dB*
Attenuation value telerance	1 dB, 2 dB, 3 dB, 4 dB, 5dB : ±0.3 dB
Allenuation value tolerance	6 dB, 10 dB:±0.5 dB
Characteristic impedance	50 Ω
Power rating at 70 ℃	0.04 W / package
Frequency range	DC to 3.0 GHz
VSWR (Voltage standing wave ratio)	1.3 max.
Number of resistors	3 resistors
Number of terminals	4 terminals
Category temperature range	−55 °C to +125 °C

* Please inquire about the other Attenuator value

Power derating curve

For resistors operated in ambient temperatures above 70 ℃, power rating shall be derated in accordance with the figure on the right.



Design and specifications are each subject to change managements. Should a safety concern arise regarding this product, please be sure to contact us immediately. 76 Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use

Chip Attenuator

Construction



Circuit configuration



Attenuation-frequency characteristics



Dimensions (not to scale)

EXB14AT



EXB24AT



< Marking Configuration>

The bar marking for recognizing terminal direction is located on the side of terminal 3, 4.

< Marking Configuration>

The bar marking for recognizing terminal direction is located on the side of terminal 4.

								Unit : mm			
Dart No	Dimensions										
Fall NO.	L	W	Т	A	В	С	P (typical value)	(g/1000 pcs)			
EXB14AT	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	0.15±0.10	0.15±0.10	0.50	0.7			
EXB24AT	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	0.15±0.10	0.25±0.10	0.65	1.1			

PER	Ind	

Surfac	e mount resistors series	3		Packaging (Standard	d quantity : pcs/reel)	
		2	Pressed	Punched	Punched	Embossed
Products	Part No.	Size (mm) (inch)	carrier taping	carrier taping	carrier taping	carrier taping
			(2 mm pitch)	(2 mm pitch)	(4 mm pitch)	(4 mm pitch)
	ERJXGN	0402 (01005)	20,000 ^{*1}	—	_	40,000 ^{*2}
	ERJ1GN	0603 (0201)	15,000	—	_	_
	ERJ2GE	1005 (0402)	—	10,000	_	_
	ERJ3GE	1608 (0603)	—	—	5,000	—
Thick film	ERJ6GE	2012 (0805)		—	5,000	_
chip resistors	ERJ8GE	3216 (1206)		—	5,000	_
	ERJ14	3225 (1210)		—	—	5,000
	ERJ12	4532 (1812)		—	—	5,000
	ERJ12Z	5025 (2010)		—	—	5,000
	ERJ1T	6432 (2512)		—	—	4,000
	ERJXGN	0402 (01005)	20,000 ^{*1}	—	—	40,000 ^{*2}
	ERJ1GN/1RH	0603 (0201)	15,000	—	_	_
	ERJ2RC/2RH/2RK	1005 (0402)		10,000	_	_
	ERJ3RB/3RE/3EK	1608 (0603)		—	5,000	_
Precision thick film	ERJ6RB/6RE/6EN	2012 (0805)		—	5,000	
chip resistors	ERJ8EN	3216 (1206)		—	5,000	
	ERJ14N	3225 (1210)		—	—	5,000
	ERJ12N	4532 (1812)		—	—	5,000
	ERJ12S	5025 (2010)		—	_	5,000
	ERJ1TN	6432 (2512)		—	_	4,000
	ERA1A	0603 (0201)	15,000	—	_	_
Metal film	ERA2A/2V	1005 (0402)		10,000	_	_
(Thin film) chip resistors.	ERA3A/3V/3K	1608 (0603)		—	5,000	_
High reliability type	ERA6A/6V/6K	2012 (0805)		—	5,000	_
	ERA8A/8V/8K/8P	3216 (1206)		—	5,000	_
	ERJ2LW/2BW	1005 (0402)	10,000	—	_	_
	ERJ2BS/2BQ	1005 (0402)	—	10,000	—	—
	ERJ3L/3B/3R/L03	1608 (0603)		—	5,000	
Thick film	ERJ6L/6B/6C ERJ6D/6R/L06	2012 (0805)	_	_	5,000	_
Low resistance type	ERJ8B/8C/8R/L08	3216 (1206)		—	5,000	
	ERJ14B/14R/L14	3225 (1210)		—	—	5,000
	ERJ12R/L12	4532 (1812)	—	—	—	5,000
	ERJ12Z/L1D	5025 (2010)	—	—	—	5,000
	ERJ1TR	6432 (2512)				4,000
Current sensing resistors	ERJMS4	6432 (2512)	_	—	—	2,000
Metal plate type	ERJMB1	2550 (1020)		—	—	3,000
	ERJA1	3264 (1225)	—	—	—	4,000
High power chip resistors/	ERJB1/ERJC1 ^{*3} ERJD1 ^{*4}	2550 (1020)	_	_	_	5,000
chip resistors/ Wide terminal type	ERJB2/ERJD2*4	1632 (0612)			5,000	_
	ERJB3	1220 (0508)			5,000	_
High precision thick	ERJPB3	1608 (0603)			5,000	
film chip resistors	ERJPB6	2012 (0805)			5,000	_
			1	. I		

*1: W8P2 : Width 8 mm, Pitch 2 mm,

*3: Anti-Sulfurated High power chip resistors / Wide terminal type

*2: W4P1 : Width 4 mm, Pitch 1 mm

*4: Low TCR High power chip Resistors / Wide terminal type

Packaging method

Surfac	e mount resistors serie	S		Packaging (Standar	d quantity : pcs/reel)	
			Pressed	Punched	Punched	Embossed
Products	Part No.	Size	carrier taping	carrier taping	carrier taping	carrier taping
		(mm) (inch)	(2 mm nitch)	(2 mm nitch)	(4 mm nitch)	(4 mm nitch)
		1005 (0402)	(2 min piton)	10,000	(4 min piton)	(4 min piton)
		1608 (0603)			5 000	
Anti-Surge Thick film		2012 (0805)			5,000	
Surfa Products Anti-Surge Thick film Chip resistors Anti-Pulse Thick film chip resistors Anti-Sulfurated Thick film chip resistors Anti-Sulfurated Thick film chip resistors Anti-Sulfurated Thick film chip resistors Precision type Anti-Sulfurated Thick film chip resistors Precision type High temperature thick film chip resistor Chip resistor Chip resistor array		2012 (0003)			5,000	
		3216 (1206)			5,000	 5.000
		3225 (1210)				5,000
Anti-Pulse Thick	ERJ106	2012 (0805)	—		5,000	
film chip resistors	ERJI08	3216 (1206)	_		5,000	
	ERJ114	3225 (1210)				5,000
	ERJU0X	0402 (01005)	20,000	_		—
	ERJU01	0603 (0201)	15,000	_		—
	ERJS02/U02	1005 (0402)		10,000	_	
	ERJS03/U03	1608 (0603)	—	_	5,000	—
Anti-Sulfurated Thick film	ERJS06/U06 ERJU6S/U6Q	2012 (0805)	_	_	5,000	—
chip resistors	ERJS08/U08	3216 (1206)	—	—	5,000	—
	ERJS14/U14	3225 (1210)			_	5,000
	ERJS12/U12	4532 (1812)	_	_	-	5,000
	ERJS1D/U1D	5025 (2010)		_	_	5,000
	ERJS1T/U1T	6432 (2512)	_			4,000
Anti Sulfuratad	ERJU2R	1005 (0402)	_	10,000		
Thick film chip resistors /	ERJU3R	1608 (0603)			5.000	
Precision type	FRJU6R	2012 (0805)			5.000	
	FRJUP3	1608 (0603)	_		5,000	
Anti-Sulfurated Thick film chip resistors /	FRJUP6	2012 (0805)			5 000	
Anti-Surge type	FRJUP8	3216 (1206)			5 000	
	ERJH2G/2C/2R	1005 (0402)		10 000		
High temperature thick	ERJH3G/3E/30	1608 (0603)			5 000	
film chip resistor	ER H6G/HP6	2012 (0805)			5,000	
	EXB14V	0806 (0302)		10 000		
	EXB24V	1010 (0404)		10,000		
	EXB34V	1616 (0606)			5 000	
		1616 (0606)			5,000	
		1406 (0502)		10.000	3,000	
Chip resistor		2010 (0804)		10,000		
array		2010 (0804)		10,000		
		2010 (0804)		10,000	 5.000	
		3216 (1200)			5,000	
		5022 (2000)			5,000	2 500
		2816 (1506)			 5.000	2,300
		3810 (1300)			5,000	
		1406 (0502)	—	10,000	_	
	EXBUIR	1406 (0502)	—	10,000	—	
Anti-Sulfurated	EXBU24	1010 (0404)	—	10,000		—
chip resistor array	EXBU34	1616 (0606)		—	5,000	—
chip resistor array	EXBU28	2010 (0804)	—	10,000		—
	EXBU38	3216 (1206)		—	5,000	—
	EXBU2H	3816 (1506)	_	—	5,000	—
	EXBD	3216 (1206)	—	—	5,000	—
Chip resistor networks	EXBE	4021 (1608)	—	—	—	4,000
	EXBA	6431 (2512)		—		4,000
	EXBQ	3816 (1506)	$\begin{array}{c c c c c c c c c c c c c c c c c c c $			
Chin attenuator	EXB14AT	0806 (0302)		10,000	<u> </u>	—
	EXB24AT	1010 (0404)		10,000	_	

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Surface Mount Resistors Packaging Method (Taping)

Carrier tape



Pressed carrier taping (2 mm Pitch)

Chip resistors / Precision chip / Metal film(Thin film)chip / Low resistance / Anti-Sulfurated Unit : mm											
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
ERJXGN ERJU0X	0402 (01005)	0.24±0.03	0.45±0.03								0.31±0.05
ERJ1GN ERJ1R□ ERJU01 ERA1A	0603 (0201)	0.38±0.05	0.68±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.42±0.05
ERJ2LW	1005 (0402)	0.68±0.10	1.20±0.10								0.60±0.05
ERJ2BW	1003 (0402)	0.67±0.10	1.17±0.10								0.61±0.05

Punche	Punched carrier taping (2 mm Pitch)										
Chip resistors / Precision chip / Thin film chip / Low resistance / Anti-Surge / Anti-Sulfur / High temperature / Metal foil type											Unit : mm
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
ERJ2 ERJPA2 ERJ ERJ ERJ ERA2	1005 (0402)	0.67±0.05	1.17±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05

• Chip resistor array / Anti-Sulfurated chip resistor Aarray / Chip attenuator

Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
EXB14V EXB14AT	0806 (0302)	0.70 +0.10/-0.05	0.95 +0.05/-0.10								
EXB18V	1406 (0502)		1.60±0.10								
EXB24V EXBU24 EXB24AT	1010 (0404)	1.20±0.10	1.20±0.10	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05
EXB28V EXBU28 EXBN8V	2010 (0804)		2.20±0.10								

Punched carrier taping (4 mm Pitch)

Chip resistors / Precision chip / Metal film(Thin film)chip / Low resistance / High power / High precision / Anti-Surge /

Anti-Pulse / Anti-Sulfurated /

Anti-Pulse	Anti-Sulfurate	d / High tem	perature								Unit : mm
Part No.	Size (inch)	A	В	W	F	Е	P ₁	P ₂	P ₀	øD ₀	Т
ERJ3 ERJ3LW(10mΩ) ERJ3BW ERJ 3 ERJ 3 ERJ 3 ERA3	1608 (0603)	1.10±0.10	1.90±0.10								0.70±0.05
ERJ3LW(5mΩ)											
ERJ6 ERJ 6 ERJ 6 ERA6 ERJB3	2012 (0805)	1.65±0.15	2.50±0.20	8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.84±0.05
ERJ6LW ERJ6CW	2012 (0805)	1.55±0.15	2.30±0.20								0.94±0.05
ERJ8 U ERJ8 W ERJ 8 ERA8 E ERJB2 ERJD2	3216 (1206) 1632 (0612)	2.00±0.15	3.60±0.20								0.84±0.05

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Should a safety concern arise regarding this product, please be sure to contact us immediately.

Unit : mm

Surface Mount Resistors Packaging Method (Taping)

Puncheo	d carrier t	aping (4	4 mm P	itcn)							
Chip resister	or array / Anti-S	Sulfurated cl	nip resistor a	array / Chip	resistor net	works					Unit : mm
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
EXB34V EXBU34	1616 (0606)		1.95±0.20								
EXB38V EXBU38	3216 (1206)		3.60±0.20								0.70±0.05
EXB2HV EXBU2H	3816 (1506)	1.95±0.15	4.10±0.15	5 8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	2.00±0.05	4.00±0.10	1.50	
EXBV4V	1616 (0606)		4.10±0.15 1.95±0.20						+0.10/0	0.94+0.05	
EXBV8V	3216 (1206)		3.60±0.20								0.0410.03
EXBD	3216 (1206)	2.00±0.20	3.60±0.20								0.84±0.10
EXBQ	3816 (1506)	1.90±0.20	4.10±0.20								0.64±0.05

Embossed carrier taping (1 mm Pitch)

Chip resistors Unit											
Part No.	Size (inch)	А	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
ERJXGN	0402 (01005)	0.25±0.05	0.45±0.05	4.00±0.20	1.80±0.05	0.90±0.10	1.00±0.10	1.00±0.10	2.00±0.10	0.80±0.10	0.5 max.

Embossed carrier taping (4 mm Pitch)

• Chip resistors / Precision chip / Low resistance / High power / Anti-Surge / Anti-Pulse / Anti-Sulfurated

 Chip resist 	ors / Precision	chip / Low r	esistance /	High power	/ Anti-Surge	e / Anti-Pi	ulse / Ant	ti-Sulfura	ted			Unit : mm
Part No.	Size (inch)	А	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
ERJ14 🗌 ERJ 🗌 14	3225 (1210)	2.80±0.20	3.50±0.20	8.00±0.30	3.50±0.05							1.00+0.10/0
ERJ12 ERJ 12	4532 (1812)	3.50±0.20	4.80±0.20									
ERJ12Z ERJ12S ERJ⊡1D	5025 (2010)	2 80+0 20	5 30+0 20			1.75	4.00	2.00	4.00	1.50	1.00±0.10	
ERJB1 ERJC1 ERJD1	2550 (1020)	2.0010.20	5.5010.20	12.00 ±0.30	5.50±0.20	±0.10	±0.10	±0.05	±0.10	+0.10/0		1.5 min.
ERJ1T 🗆 ERJ 🗆 1T	6432 (2512)	3.60±0.20	6.90±0.20									
ERJL1W											1.60±0.10	
ERJA1	3264 (1225)	3.50±0.20	6.80±0.20]							1.10±0.20	

• Current sensing resistors, Metal plate type

 Current ser 	nsing resistors,	Metal plate	type									Unit : mm
Part No.	Size (inch)	A	В	W	F	Е	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
ERJMB1	2550 (1020)	2.90±0.20	5.40±0.20	12.00 ±0.30	5.50±0.10	1.75	4.00	2.00	4.00	1.50	1.55±0.20	
ERJMS4	6432 (2512)	3.50±0.20	6.90±0.20	12.00 ±0.30	5.50±0.10	±0.10	±0.10	±0.05	±0.10	+0.10/0	1.60±0.20	1.5 min.

Chip resistor array / Chip resistor networks Unit : mm												Unit : mm
Part No.	Size (inch)	А	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
EXBS8V	5022 (2009)	2.80±0.20	5.70±0.20				1.00		1.00	4.50	1.6 max.	
EXBE	4021 (1608)	2.50±0.20	4.40±0.20	12.00±0.30	5.50±0.20	1.75 +0.10	4.00 ±0.10	2.00 ±0.05	4.00 +0.10	1.50 +0.10/0	1 10+0 20	1.5 min.
EXBA	6431 (2512)	3.50±0.20	6.80±0.20			20.10	20110	20.00	20.10	0110/0	1.1010.20	

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Taping reel



Cape width (W)			Dimensions		
	øA	øN	øC	W ₁	W_2
4 mm width	180.0±3.0			4.5±0.5	7.0±0.5
8 mm width	190 0 0/ 1 5	60.0+1.0/0	12.010.2	9.0+1.0/0	11.4±1.0
12 mm width	180.0 0/-1.5 380 0+2 0		13.0±0.2	13.0+1.0/0	15.4±1.0
24 mm width	380.0±2.0	80.0±1.0		25.4±1.0	29.4±1.0

Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use.

Should a safety concern arise regarding this product, please be sure to contact us immediately.

[Discontinued product]

Packaging method

Surfac	e mount resistors serie	S		Packaging (Standar	d quantity : pcs/reel)	
		Sizo	Pressed	Punched	Punched	Embossed
Products	Part No.	(mm) (inch)	carrier taping	carrier taping	carrier taping	carrier taping
			(2 mm pitch)	(2 mm pitch)	(4 mm pitch)	(4 mm pitch)
Thick film chip resistors/ Low resistance type	ERJL1W	6432 (2512)	_	_	_	3,000
	ERJMP2	3216 (1206)	—	—	—	3,000
Current sensing	ERJMP3	5025 (2010)	—	—	—	3,000
resistors,	ERJMP4	6432 (2512)	—	—	—	2,000
Metal plate type	ERJMS6	6468 (2526)	—	—	—	1,000 (8mm Pitch)
	ERJM1W	6432 (2512)	—	—	—	3,000
Current sensing resistors, Metal foil type	ERJMFBA	1005 (0402)	_	10,000	_	_

Carrier tape



Punched carrier taping (2 mm Pitch)

Chip resistors / Precision chip / Thin film chip / Low resistance / Anti-Surge / Anti-Sulfur / High temperature / Metal foil type												
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	
ERJMFBA	1005 (0402)	0.67±0.05	1.17±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.60±0.05	

Embossed carrier taping (4 mm Pitch)

Chip resistors / Precision chip / Low resistance / High power / Anti-Surge / Anti-Pulse / Anti-Sulfurated												
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
ERJL1W	6432 (2512)	3.60±0.20	6.90±0.20	12.00 ±0.30	5.50±0.20	1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.60±0.10	1.5 min.

Current sensing resistors, Metal plate type Unit : mr												
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	øD1
ERJMP2 (1 mΩ)	3216 (1206)										1.55±0.20	_
ERJMP2 (2 mΩ)	3216 (1206)	1.90±0.20	3.50±0.20	8.00±0.30	3.50±0.10						1.40±0.20	_
ERJMP2 (3~50 mΩ)	3216 (1206)										1.10±0.20	_
ERJMP3 (1 ~2 mΩ)	5025 (2010)	2 00+0 20	5 40+0 20	12.00	5 50±0 10	1.75	4.00	2.00	4.00	1.50	1.55±0.20	—
ERJMP3 (3~50 mΩ)	5025 (2010)	2.9010.20	5.4010.20	±0.30	5.5010.10	10.10	10.10	10.05	10.10	+0.10/0	1.15±0.20	_
ERJMP4 (1 ~2 mΩ)	6432 (2512)			40.00							1.60±0.20	1.5 min.
ERJMP4 (3~50 mΩ)	6432 (2512)	3.50±0.20	6.90±0.20	±0.30	5.50±0.10						1.20±0.20	_
ERJM1W	6432 (2512)										1.80±0.20	1.5 min.

Embossed carrier taping (8 mm Pitch)

• Current ser	nsing resistors,	Metal plate	type									Unit : mm
Part No.	Size (inch)	A	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
ERJMS6	6468 (2526)	6.90±0.20	7.50±0.20	12.00	5.50±0.05	1.75	8.00 ±0.10	2.00	4.00	1.50	2.45±0.20	1.5 min.
		1	1	10.30	1	TO: 10	10.10	T0.02	10.10	+0.10/0		

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Should a safety concern arise regarding this product, please be sure to contact us immediately.

Recommended land pattern

- An example of a land pattern for the rectangular type is shown below.
- <Ex.>



High power (double-sided resistive elements structure) type

Part No	Size	Dimensions			
i artivo.	(inch)	а	b	С	
ERJ2LW/2BW	1005 (0402)	0.52	1.4 to 1.6	0.4 to 0.6	
ERJ3LW/3BW	1608 (0603)	0.5 to 0.8	2.5 to 2.7	0.9 to 1.1	
ERJ6LW		0.6 to 0.8	3.2 to 3.8	1.1 to 1.4	
ERJ6BW		0.9	3.2 to 3.8	1.1 to 1.4	
ERJ6CW	2012	0.7 to 0.0	2 0 to 2 0	1 1 to 1 1	
(10 to 13 mΩ)	(0805)	0.7 10 0.9	3.2 10 3.0	1.1 10 1.4	
ERJ6CW		0.0 to 1.1	2 0 to 2 0	1 1 to 1 1	
(15 to 30 mΩ)		0.9 10 1.1	3.2 10 3.0	1.1 10 1.4	
ERJ8BW					
ERJ8CW	1	1.2	4.4 to 5.0	1.3 to 1.8	
(10 to 16 mΩ)	3216				
ERJ8CW	(1200)	2.0 to 2.6	1 1 to 5 0	1 2 to 1 9	
(18 to 50 mΩ)		2.0 10 2.0	4.4 (0 5.0	1.2 10 1.0	
Unit : mm					

High temperature type (ERJH) High precision type (ERA) Current sensing type (ERJ*L/B/C, ERJ*R, ERJL) Small & high power type (ERJP, ERJT) Anti-sulfurated type (ERJS, ERJU) General purpose type (ERJ)

Wide terminal type (ERJA/B/Ds)						
Size						
mm/inch	а	b	С			
0402/01005	0.15 to 0.20	0.5 to 0.7	0.20 to 0.25			
0603/0201	0.3 to 0.4	0.8 to 0.9	0.25 to 0.35			
1005/0402	0.5 to 0.6	1.4 to 1.6	0.4 to 0.6			
1608/0603	0.7 to 0.9	2.0 to 2.2	0.8 to 1.0			
2012/0805	1.0 to 1.4	3.2 to 3.8	0.9 to 1.4			
3216/1206	2.0 to 2.4	4.4 to 5.0	1.2 to 1.8			
3225/1210	2.0 to 2.4	4.4 to 5.0	1.8 to 2.8			
4532/1812	3.3 to 3.7	5.7 to 6.5	2.3 to 3.5			
5025/2010	3.6 to 4.0	6.2 to 7.0	1.8 to 2.8			
6432/2512	5.0 to 5.4	7.6 to 8.6	2.3 to 3.5			
6432/2512*	3.6 to 4.0	7.6 to 8.6	2.3 to 3.5			

* ERJL1W

• An example of a land pattern for high power chip resistors / Wide terminal type is shown below.



			Unit : mm		
Part No	Dimensions				
Tarrito.	а	b	С		
ERJA1	6.4	1.70	0.60		
ERJB1					
ERJC1 ^{*1}	5.0	1.30	0.75		
ERJD1 ^{*2}					
ERJB2	2.2	0.05	0.70		
ERJD2 ^{*2}	5.2	0.95	0.70		
ERJB3	2.0	0.80	0.60		

*1: Anti-Sulfurated High power chip resistors / Wide terminal type

*2: Low TCR High power chip resistors / Wide terminal type

Recommended land pattern

• An example of a land pattern for Chip Resistor Array, Anti-Sulfurated Chip Resistor Array and Chip Attenuator is shown below. Unit : mm



Part No	Dimensions					
Fait NO.	а	b	С	d		
EXB14V EXB14A	0.30	0.30	0.30	0.80 to 0.90		
EXB24V EXBU24 EXB24A	0.5	0.35 to 0.40	0.30	1.4 to 1.5		



					Unit : mm			
Part No		Dimensions						
Part No.	а	b	С	d	f			
EXB28V EXBU28	0.40	0.525	0.25	0.25	1.40			
EXBN8V	0.45 to 0.50	0.35 to 0.38	0.25	0.25	1.40 to 2.00			

Unit : mm



Deut Me	Dimensions							
Part No.	а	b	С	f	Р			
EXB18V	0.20 to 0.30	0.15 to 0.20	0.15 to 0.20	0.80 to 0.90	0.40			
EXBV4V EXBV8V	0.7 to 0.9	0.4 to 0.45	0.4 to 0.45	2 to 2.4	0.80			
EXB34V EXB38V EXBU34 EXBU38	0.7 to 0.9	0.4 to 0.5	0.4 to 0.5	2.2 to 2.6	0.80			
EXBS8V	1 to 1.2	0.5 to 0.75	0.5 to 0.75	3.2 to 3.8	1.27			



				Unit : mm		
	Dimensions					
а	b	С	d	f		
1.00	0.425	0.25	0.25	2.00		

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EXB2HV

EXBU2H

Recommended land pattern

• An example of a land pattern for Chip Resistor Networks is shown below.



* When designing high density land patterns, examine the reliability of isolation among the lines and adopt the chip resistor networks.

Recommended soldering conditions (Rectagular type)

Recommendations and precautions are described below.

- Recommended soldering conditions for reflow
 Reflow soldering shall be performed a maximum of two times.
 - Please contact us for additional information when used in conditions other than those specified.
 - •Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



For soldering (Example : Sn/Pb)				
	Temperature	Time		
Preheating	140 ℃ to 160 ℃	60 s to 120 s		
Main heating	Above 200 ℃	30 s to 40 s		
Peak	235 ± 5 ℃	max. 10 s		

For lead-free soldering (Example : Sn/Ag/Cu)

	Temperature	Time
Preheating	150 ℃ to 180 ℃	60 s to 120 s
Main heating	Above 230 ℃	30 s to 40 s
Peak	max. 260 ℃	max. 10 s

• Recommended soldering conditions for flow

	For so	Idering	For lead-fre	e soldering
	Temperature	Time	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s	150 ℃ to 180 ℃	60 s to 120 s
Soldering	245 ± 5 ℃	20 s to 30 s	max. 260 ℃	max. 10 s

Recommended soldering conditions (Chip resistor array / networks and Chip attenuator)

Recommendations and precautions are described below.

Recommended soldering conditions for reflow

- •Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



For soldering (Example : Sn/Pb)

	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

For lead-free soldering (Example : Sn/Ag/Cu)

	Temperature	Time			
Preheating	150 ℃ to 180 ℃	60 s to 120 s			
Main heating	Above 230 ℃	30 s to 40 s			
Peak	max. 260 ℃	max. 10 s			

Flow soldering

We do not recommend flow soldering, because a solder bridge may form. Please contact us regarding flow sol der ing of EXBA series.

Standard for resistance value and resistance tolerance

Basis standard

IEC Publication	60062	: Marking codes for resistors and capacitors.
IEC Publication	60063	: Preferred number series forresistors and capacitors.
JIS C 5062	: Marking co	des for resistors and capacitors.
JIS C 5063	: Preferred n	umber series for resistors and capacitors.

Resistance values

The resistance values are notched by "Ratio" below in each series.

Series	Resistance tolerance (Standard)	Ratio	Remarks				
E6	±20 %	⁶ √10=1.46					
E12	±10 %	¹² √10=1.21					
E24	± 5%	²⁴ √10=1.10	Please refer to standard resistance values shown on this catalog.				
E48	± 2 %	⁴⁸ √10=1.05					
E96	± 1%	⁹⁶ √10=1.02					

How to express the resistance value with a Panasonic part number

The resistance value expressed in ohms is iden tified by a three digit number or a four digit number.

The last digit specifies the number of zeroes to follow.

The letter "R" shall be used as the decimal point for less than 10 $\Omega.$

The examples of a three digit number

Resistance code	Value in ohms (Ω)
R56	0.56
5R6	5.6
100	10
271	270
102	1 k
273	27 k
104	100 k
275	2.7 M
106	10 M
107	100 M

The examples of a four digit number

Resistance code	Value in ohms (Ω)				
R562	0.562				
5R62	5.62				
56R2	56.2				
1000	100				
2711	2.71 k				
1002	10 k				
2713	271 k				
1004	1 M				
2751	2.71 M				
1006	100 M				

How to express the resistance tolerance with a Panasonic part number

The resistance tolerance is identified by a single letter in accordance with the following table and the code is placed just before the resistance code in the following examples.

Tolerance code	Tolerance (%)	Examples				
W	± 0.05	W1001 : 1000 Ω ± 0.05 %				
В	± 0.1	B1001 : 1000 Ω ± 0.1 %				
С	± 0.25	C1001 : 1000 Ω ± 0.25 %				
D	± 0.5	D1001 : 1000 Ω ± 0.5 %				
F	± 1	F1001 : 1000 Ω ± 1 %				
G	± 2	G1001 : 1000 Ω ± 2 %				
J	± 5	J101:100 Ω ± 5 %				
К	± 10	K101:100 Ω ± 10 %				
М	± 20	M101 : 100 Ω ± 20 %				

Standard resistance values

E6	E12	E24	E48	E96	E6	E12	E24	E48	E96	E6	E12	E24	E48	E96
			100	100				215	215			47	464	464
			100	102					221					475
	10	10	405	105			22		226				487	487
			105	107				226	232		47			499
			110	110		22		007	237		47	51		511
		11		113				237	243				511	523
			445	115			24	240	249				536	536
			115	118				249	255					549
10			101	121	22			004	261	47		56	562	562
		12	121	124				201	267					576
			407	127				074	274				590	590
			127	130			27	274	280		FG			604
	12	13	400	133				007	287		56	62	619	619
			133	137		27		287	294					634
			140	140				201	301				649	649
				143			30	301	309					665
			147	147				316	316		68	68	681	681
		15	147	150			33		324					698
			154	154				332	332				715	715
				158					340					732
	15		162	162		22		249	348			75	750	750
				165		33		340	357				750	768
			169	169				365	365				787	787
				174			50		374	68				806
15			179	178	33			383	383	00			005	825
		18	178	182				505	392			82	025	845
	18		197	187			39	402	402				866	866
			107	191					412		82			887
			106	196		39		422	422			91	000	909
			196	200					432				909	931
			205	205			43	442	442				953	953
			205	210					453					976

Safty Precautions

When using our products, no matter what sort of equipment they might be used for, be sure to confirm the applications and environmental conditions with our specifications in advance.



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